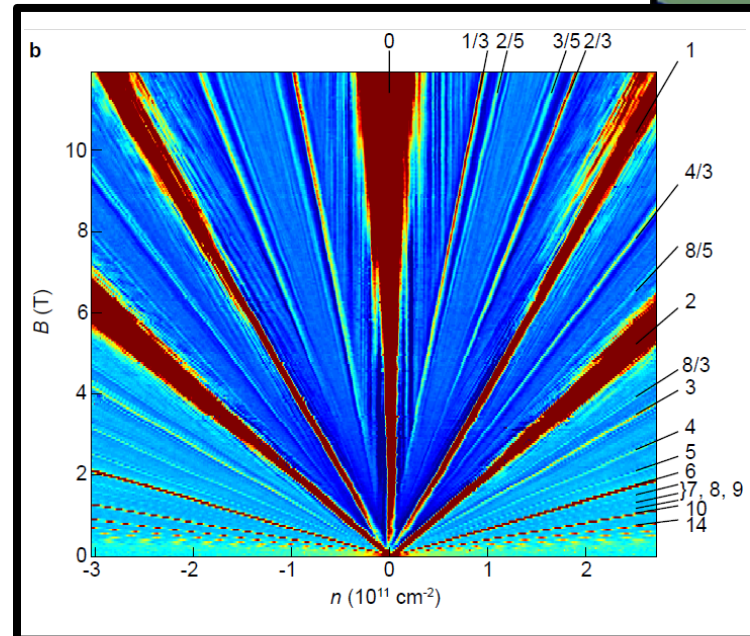
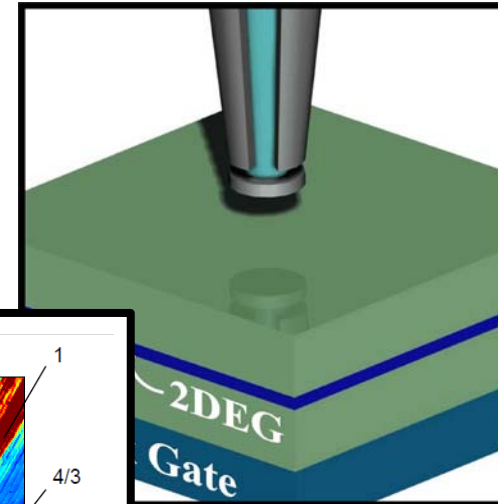


Effects of Interactions in Suspended Graphene

Ben Feldman, Andrei Levin, Amir Yacoby, Harvard University

- Broken and unbroken symmetries in the lowest LL:
 - spin and valley symmetries.
- FQHE

Discussions with Bert Halperin
and Dima Abanin



In collaboration with
Benjamin Krauss, Jurgen Smet, MPI Stuttgart

Degeneracy and Interactions

- Kinetic energy (Pauli exclusion) vs Interaction energy

$$r_s = \frac{E_{e-e}}{E_K} = \frac{e^2 / \epsilon r}{E_F}$$

$$E_{e-e} = \frac{e^2}{\epsilon r} = \frac{e^2}{\epsilon} \sqrt{n}$$

$$E_F = \frac{\hbar^2 k_F^\alpha}{2m^*} \quad n \propto g \cdot (k_F)^d$$

α - Dispersion – 1-graphene
2 - bilayer

g - Degeneracy: spin, layer, valley

d - Dimensionality (1d,2d,3d)

$$r_s \propto g^{\frac{1}{d}} \cdot n^{\frac{1}{2} - \frac{\alpha}{d}} \cdot \frac{m^*}{\epsilon}$$

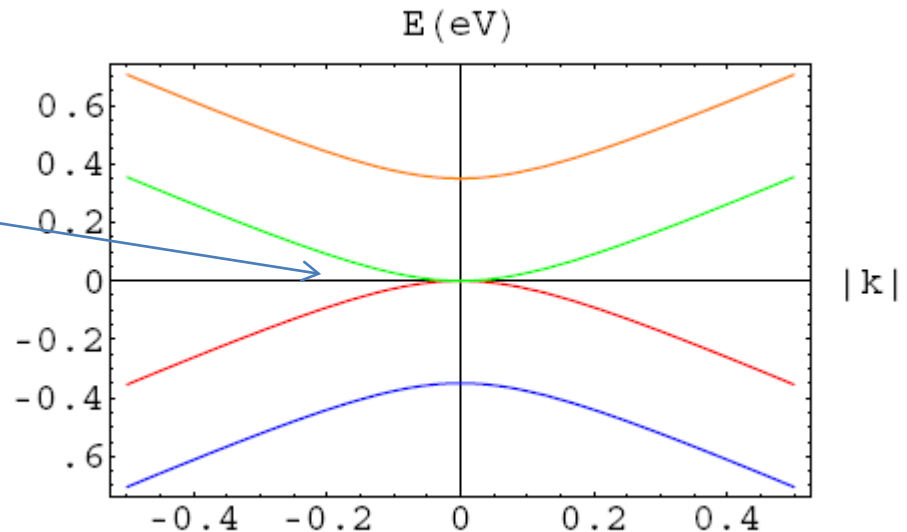
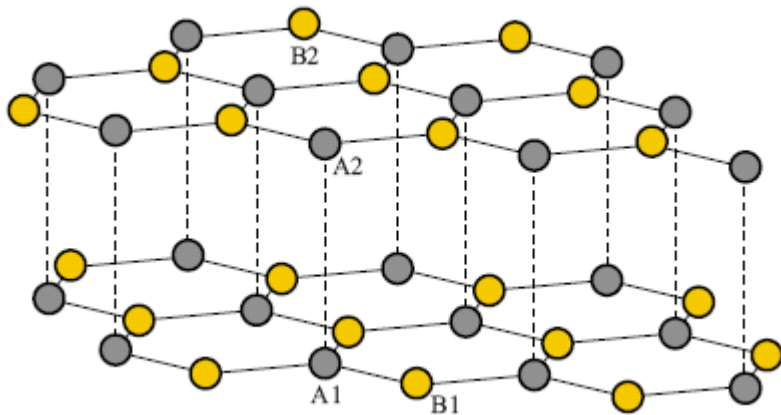
We want:

Large degeneracy, large mass, low density,
low dielectric.

Bilayers - Band Structure

- B=0

- Quadratic dispersion: $\alpha=2$
 $m \sim 0.03m_e$
- Near $E=0$; $g = 8$ - Spin, valley and sub-lattice
- Low density
- Suspended - $\epsilon \sim 1$



$$r_s \propto g^{\frac{1}{d}} \cdot n^{\frac{1}{2} - \frac{\alpha}{d}} \cdot \frac{m^*}{\epsilon}$$

Degenerate bands correspond to B1 and B2 sub-lattices

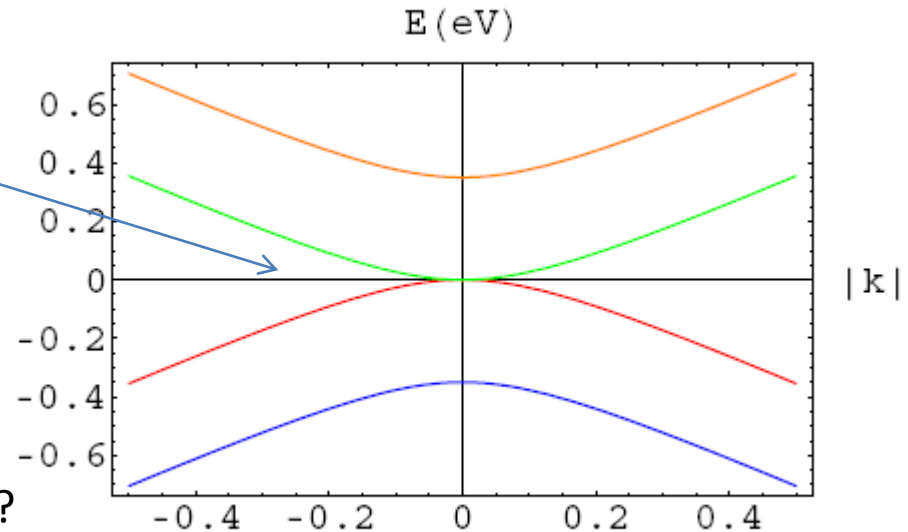
Generalization to Multi-layers

- B=0
- For N layers: ABCABC... stacking

• Dispersion $\propto k^N \rightarrow \alpha = N$

- g - Spin, valley and sub-lattice
- Low density

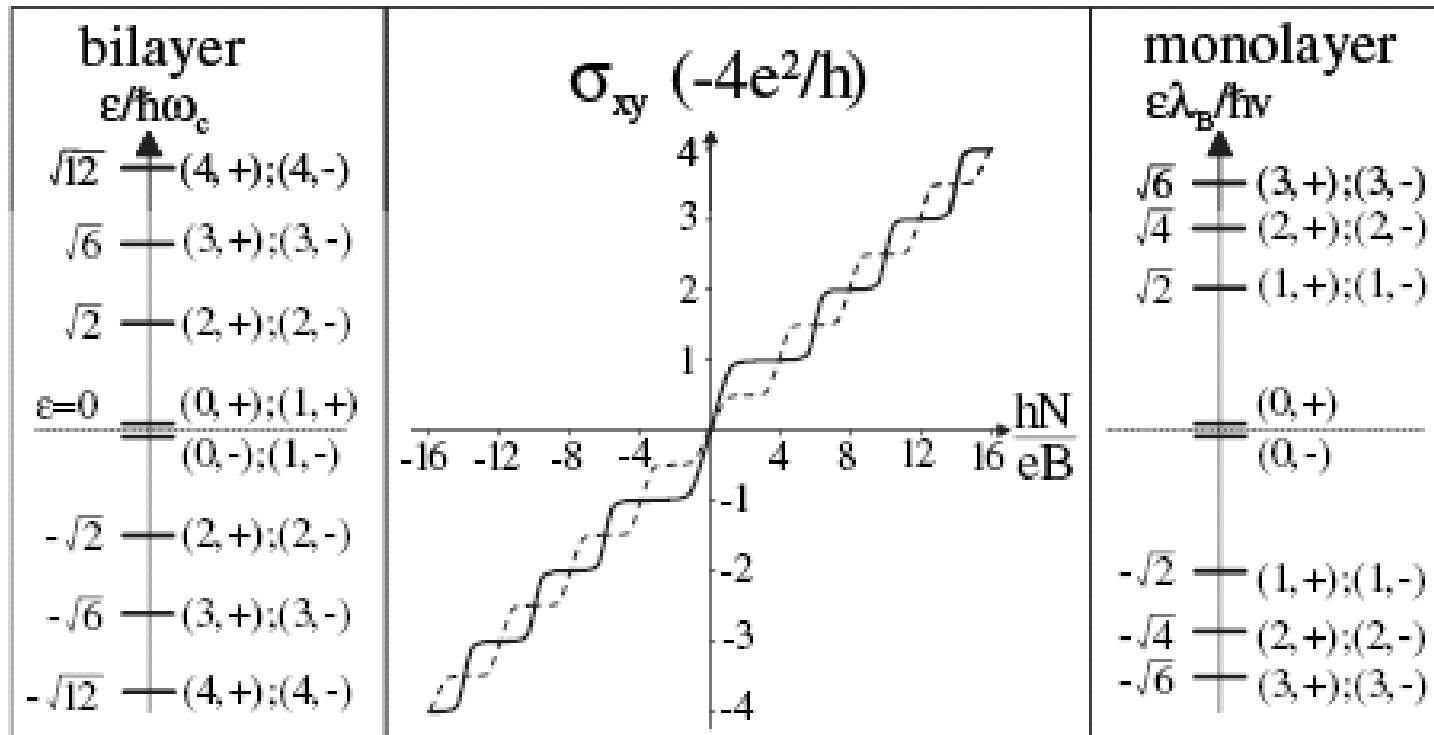
$$r_s \propto g^{\frac{1}{d}} n^{\frac{1}{2} - \frac{N}{d}} \frac{m^*}{\mathcal{E}} \quad \text{Screening?}$$



Experiments: Lau, Tarucha, Jarillo-Herrero, Kim, Zaliznyak, Geim, Novoselov, Andrei, Heintz, Crommie, Schoenenberger, Ong...

Theory: Falko, McCann, Levitov, Katsnelson, Castro-Neto, Macdonald, Fogler, Fertig, Shimshoni, Das Sarma, Polini, Guinea, Aleiner, Altshuler, Abanin, Sondhi, Kharitonov...

QHE - Degeneracy's

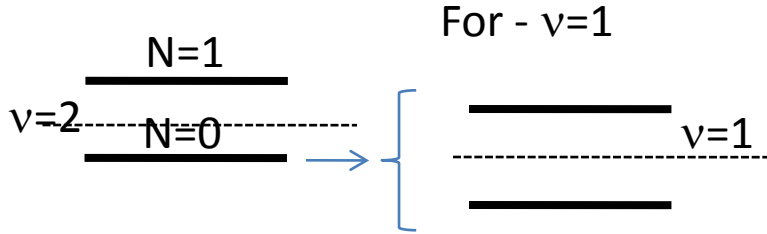


$$E_n = \hbar\omega_c \sqrt{n(n-1)}$$

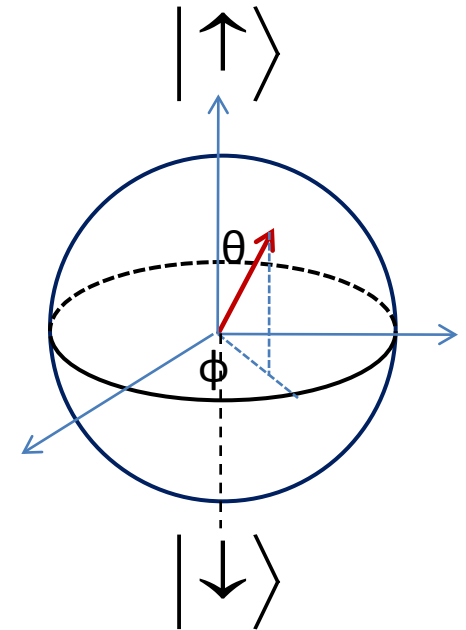
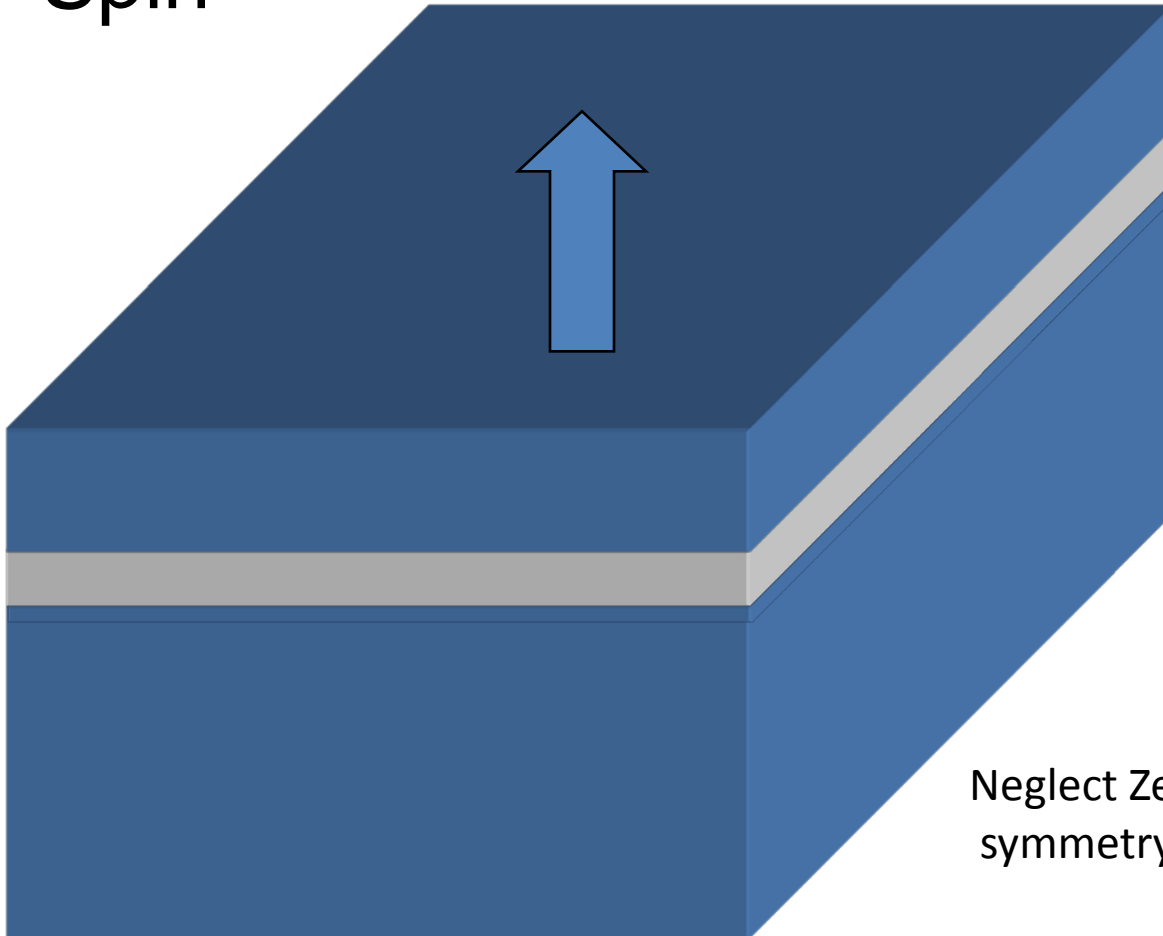
$$E_n = \sqrt{n} \sqrt{2e\hbar v_F^2 B}$$

Diverging mass

Quantum Hall Ferromagnetism



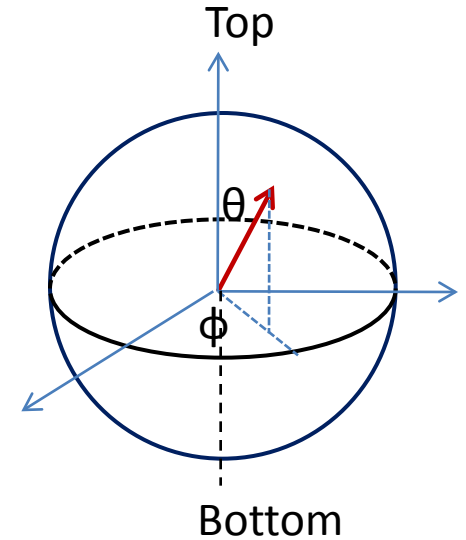
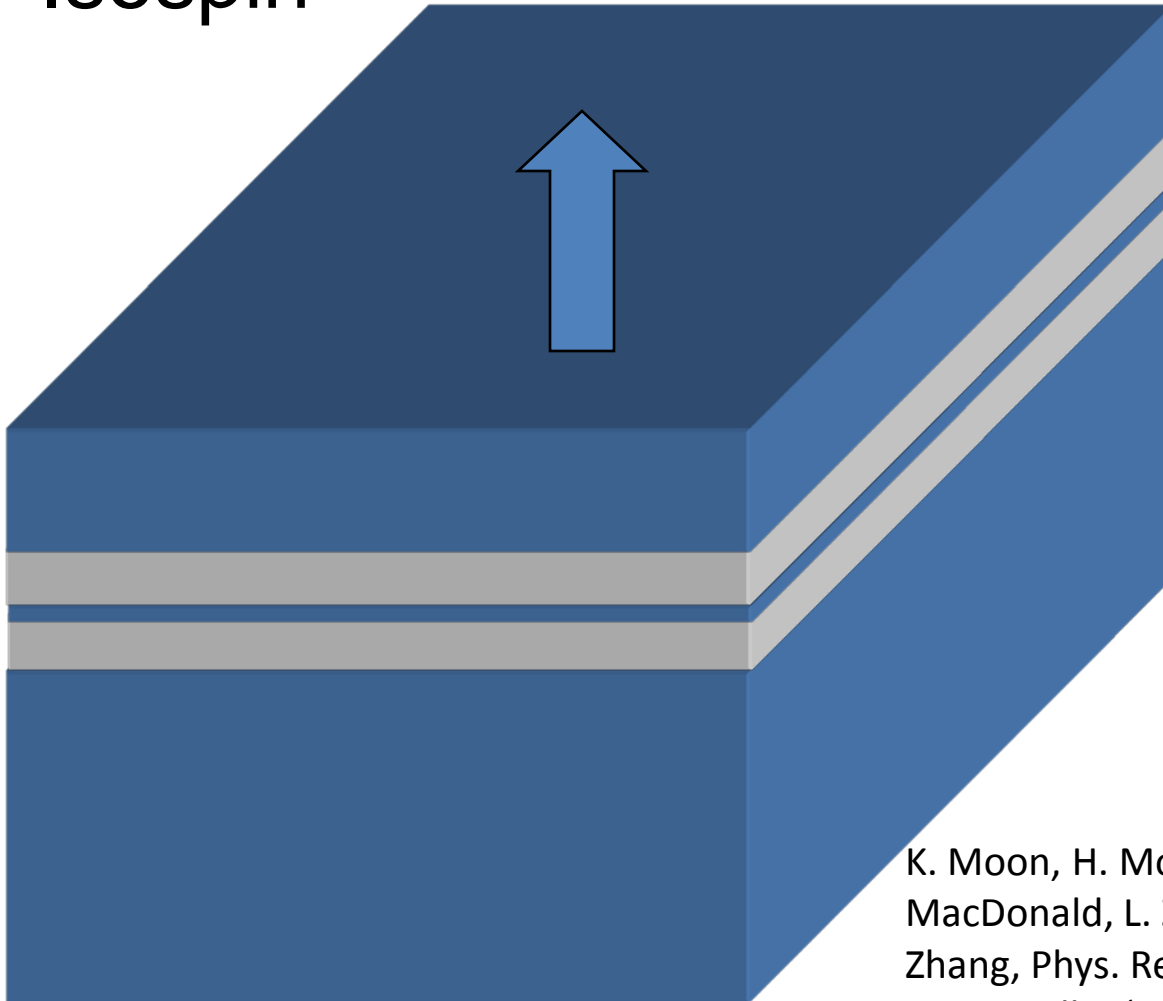
- Spin



Neglect Zeeman: SU(2) spontaneous symmetry breaking

Quantum Hall Ferromagnetism

- Isospin



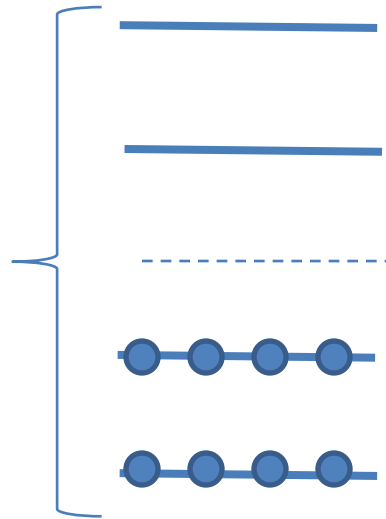
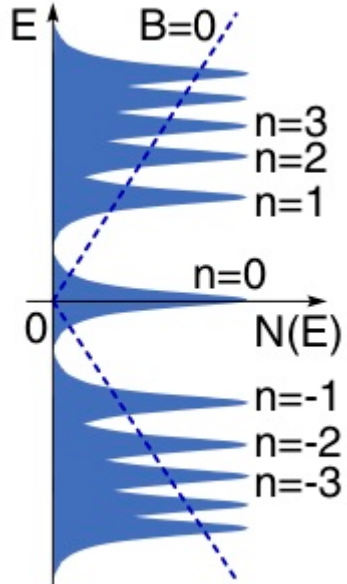
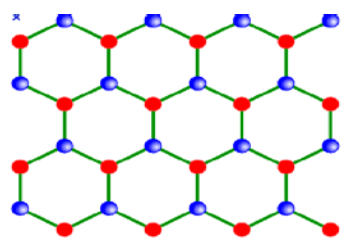
K. Moon, H. Mori, Kun Yang, S. M. Girvin, A. H. MacDonald, L. Zheng, D. Yoshioka, and Shou-Cheng Zhang, Phys. Rev. B **51**, 5138 1995.
S. L. Sondhi, '95

Simple example - $\nu=1$

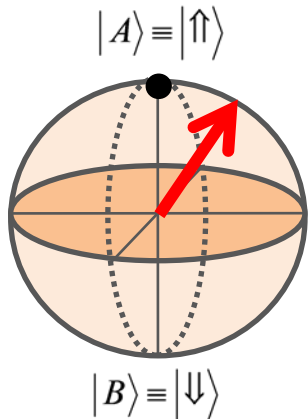
Monolayer and Bilayers

Interplay between valley and spin:

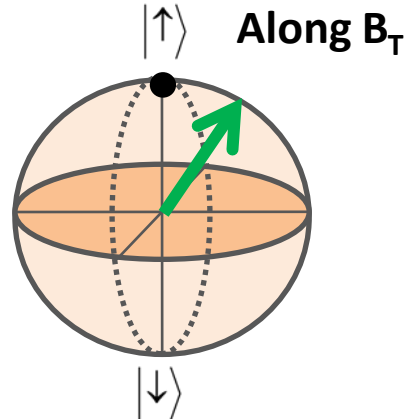
- Lowest LL occupied by electrons and holes
- 4 fold degenerate: Valley and spin



Valley/ sub-lattice (pseudospin)



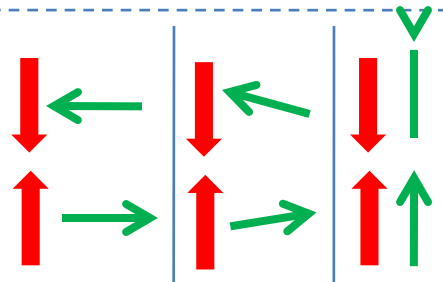
spin



Space of symmetries SU(4)

$\nu=0$

Partial spin ordering

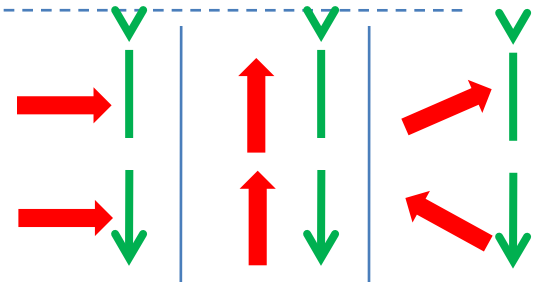


AF CAF F



Increasing Zeeman

Partial valley ordering

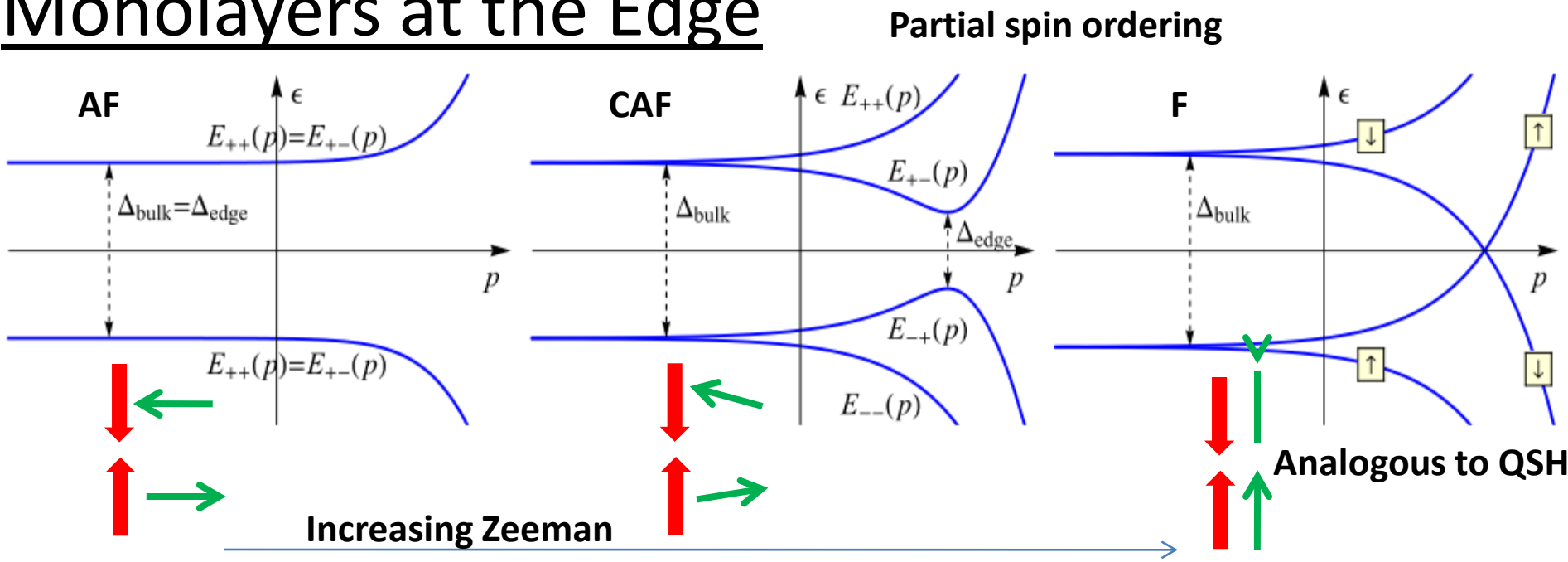


Kekule CDW PLP-Bilayers

Determined by lattice scale anisotropy

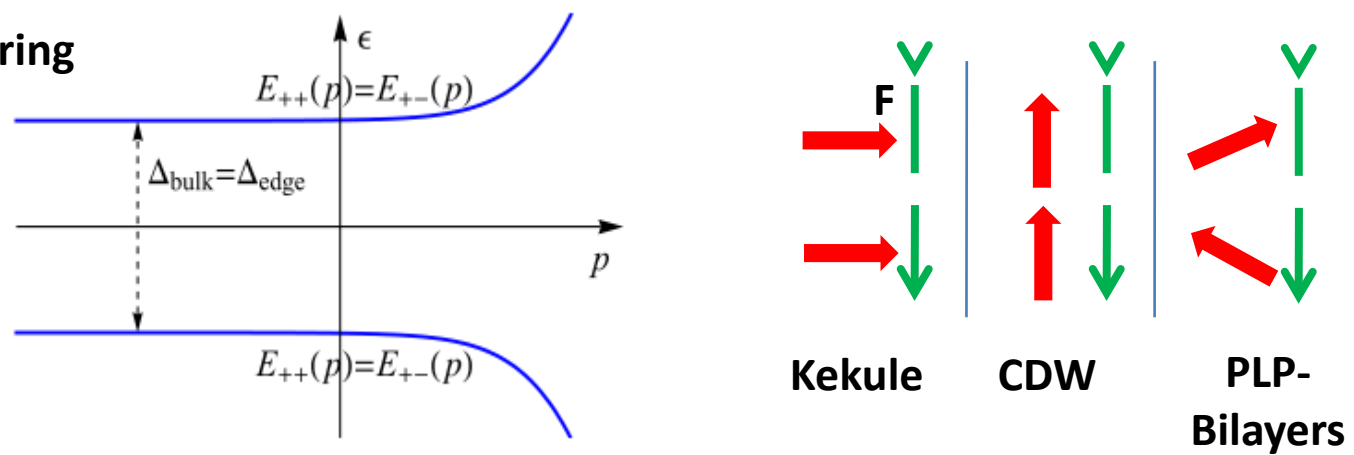
Abanin et al '07, Macdonald et al, M. Kharitonov '11, '12...

Monolayers at the Edge



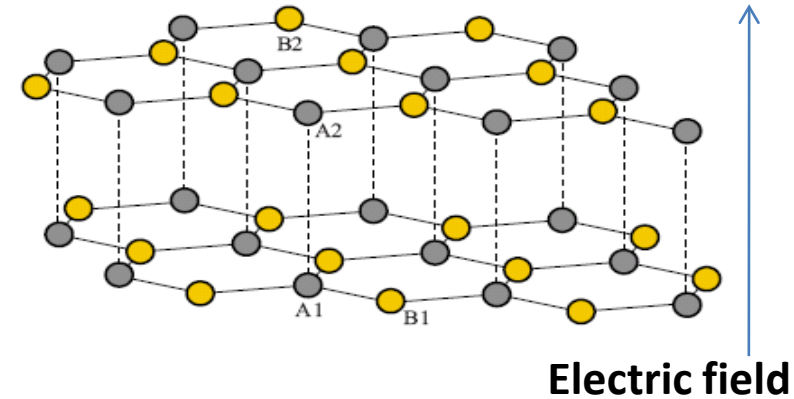
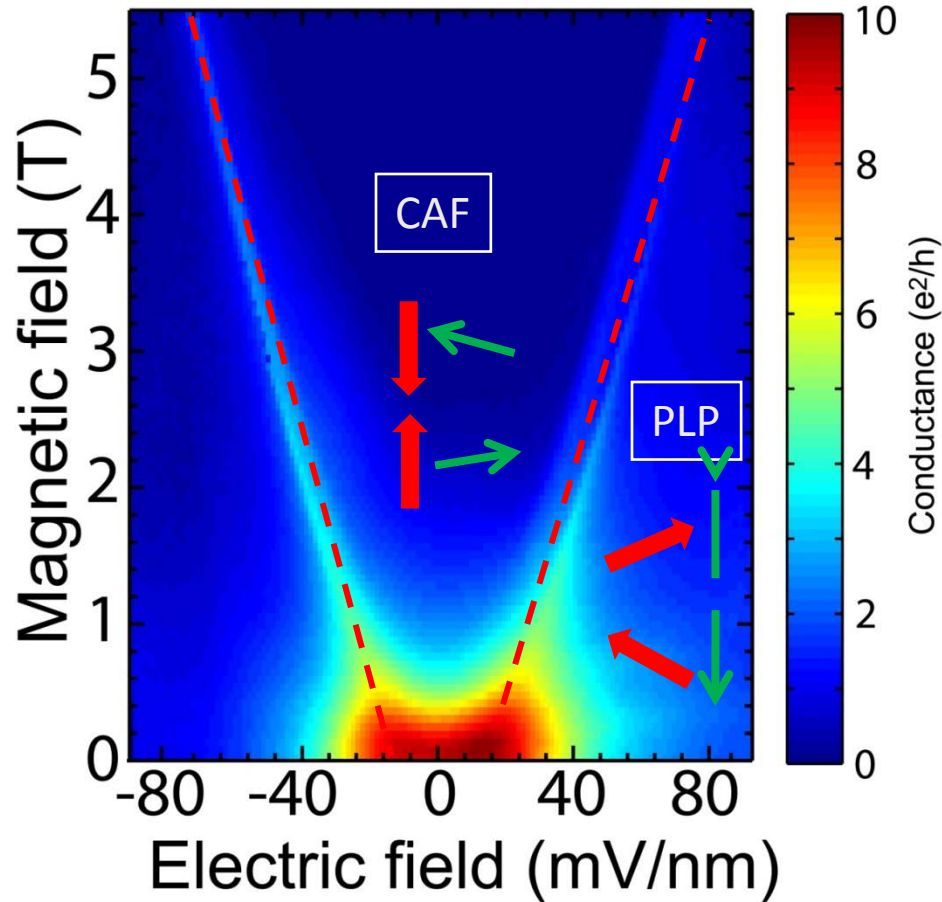
Kharitonov '12

Partial valley ordering

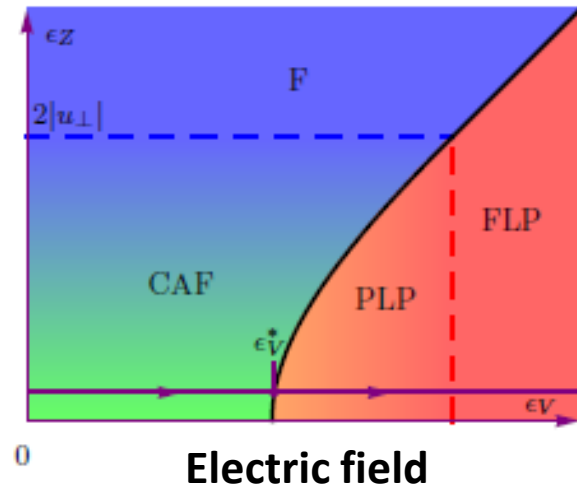


Experimentally (Kim group): Increasing Zeeman reduces transport gap; suggests absence of strong spin polarization – ?? CAF ??

Phase diagram for $\nu=0$ in Bilayers



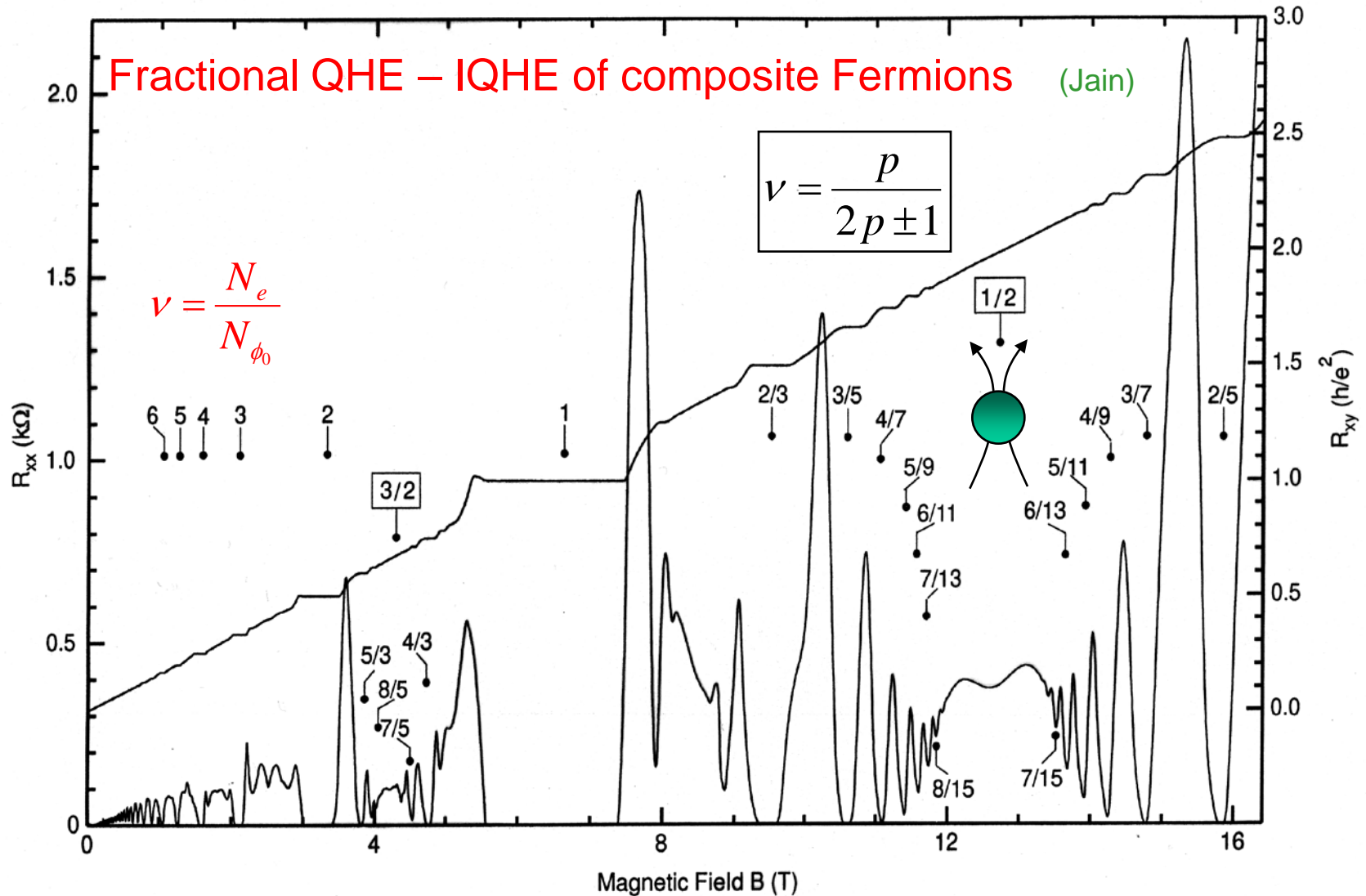
Zeeman



From: Kharitonov, 2011

See also: Macdonald, Levitov

Fractional Quantum Hall Effect - GaAs



- Non Abelian phases at 5/2 and 12/5 ?? (Moore and Read) J. Smet, V. Umansky
- Edge reconstruction (Barak, AY et al)
- Neutral edge excitation modes (Heiblum et al, Venkatachalam, AY et al)

Fractional topological phases and broken time reversal symmetry in strained graphene

Pouyan Ghaemi,^{1,2,3,*} Jérôme Cayssol,^{2,4,5} Donna N. Sheng,⁶ and Ashvin Vishwanath^{2,3}

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²*Department of Physics, University of California, Berkeley, California 94720, USA*

³*Materials Sciences Division, Lawrence Berkeley National Laboratory, Berkeley, CA 94720*

⁴*Univ. Bordeaux and CNRS, LOMA, UMR 5798, F-33400 Talence, France*

⁵*Max-Planck-Institut für Physik Komplexer Systeme, Nöthnitzer Str. 38, 01187 Dresden, Germany*

⁶*Department of Physics and Astronomy, California State University, Northridge, California 91330, USA*

We show that strained or deformed honeycomb lattices are promising platforms to realize fractional topological quantum states in the absence of any magnetic field. The strained induced pseudo magnetic fields are oppositely oriented in the two valleys [1-3] and can be as large as 60-300 Tesla as reported in recent experiments [4,5]. For strained graphene at neutrality, a spin or a valley polarized state is predicted depending on the value of the onsite Coulomb interaction. At fractional filling, the unscreened Coulomb interaction leads to a valley polarized Fractional Quantum Hall liquid which spontaneously breaks time reversal symmetry. Motivated by artificial graphene systems [5-8], we consider tuning the short range part of interactions, and demonstrate that exotic valley symmetric states, including a valley Fractional Topological Insulator and a spin triplet superconductor, can be stabilized by such interaction engineering.

arXiv:1111.3640v2 19 May 2012

Fractionalizing Majorana fermions: non-abelian statistics on the edges of abelian quantum Hall states

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Erez Berg^{*}

Department of Physics, Harvard University, Cambridge, MA 02138, USA

Gil Refael

Department of Physics, California Institute of Technology, Pasadena, CA 91125, USA

Ady Stern

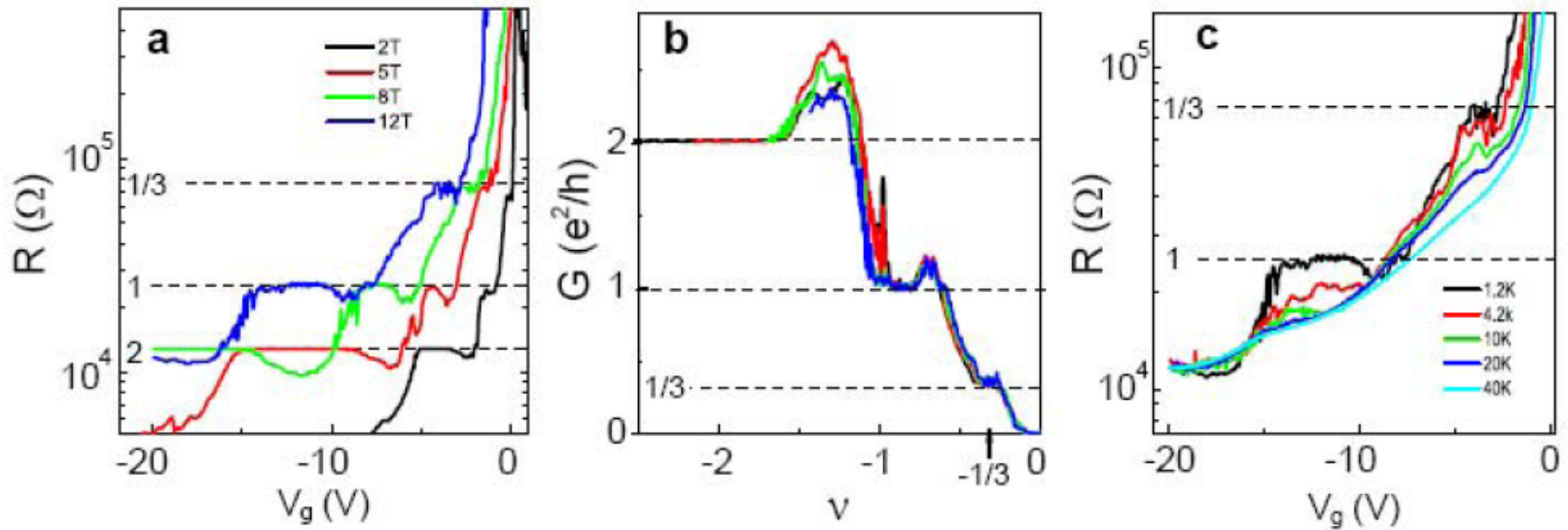
Department of Condensed Matter Physics, Weizmann Institute of Science, Rehovot 76100, Israel

(Dated: July 9, 2012)

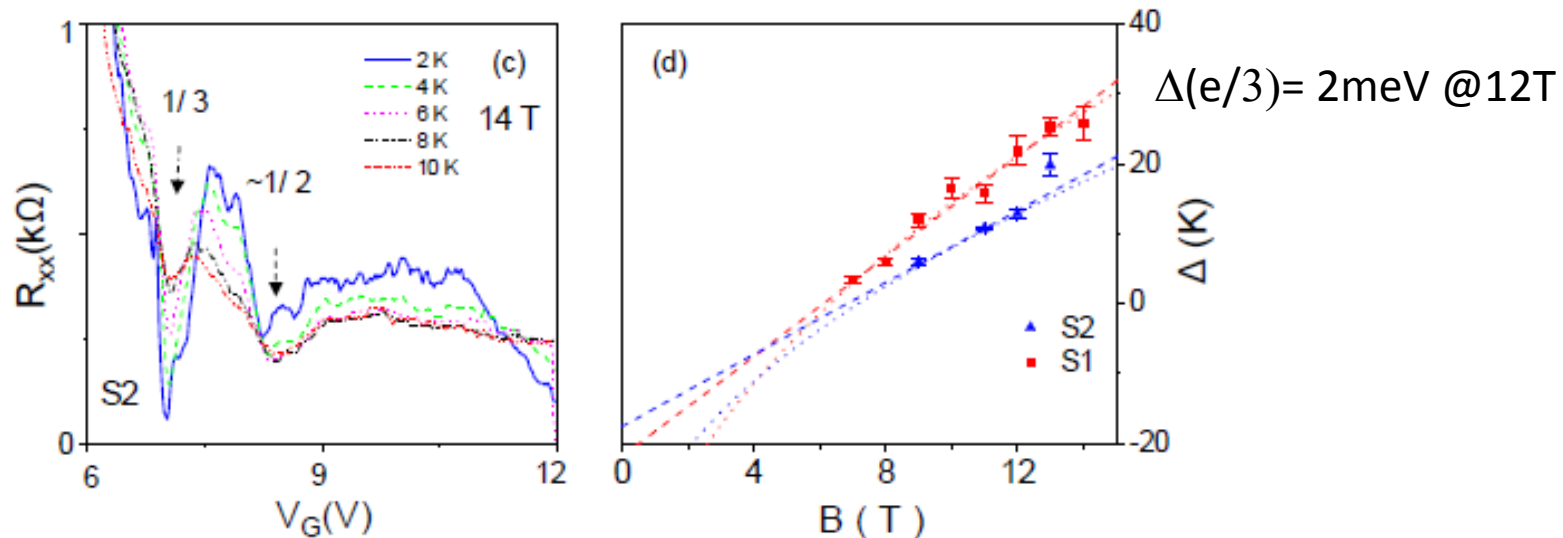
lator phase (as of today), one could get by starting from “ordinary” Laughlin fractional quantum Hall state whose edges are coupled to a superconductor. The fractional quantum Hall state in graphene might be a promising candidate for realizing such systems, since the magnetic fields needed for observing it are much lower than the fields needed in semiconductor heterostructure devices.

An experimentally accessible signature of the fractionalized Majorana modes is a fractional Josephson effect,

Background on FQHE - Suspended



Andrei group: Nature 462, 192, (2009)



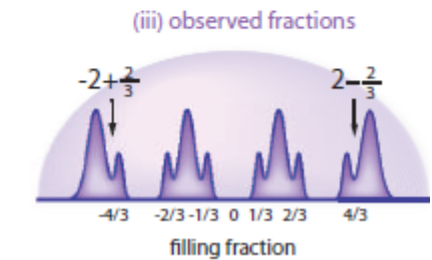
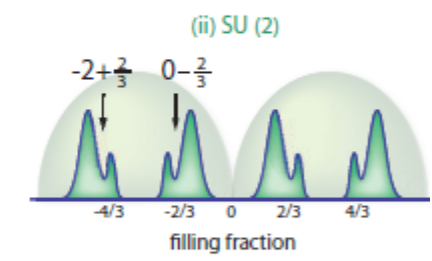
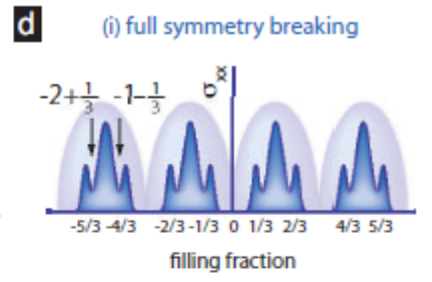
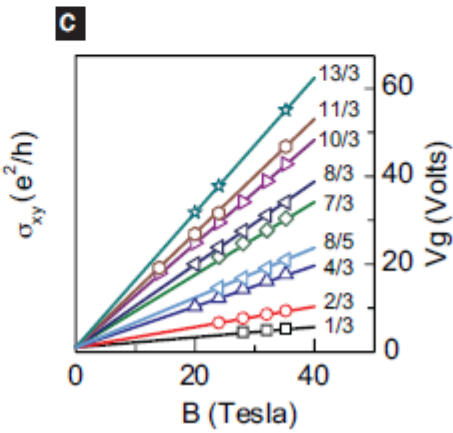
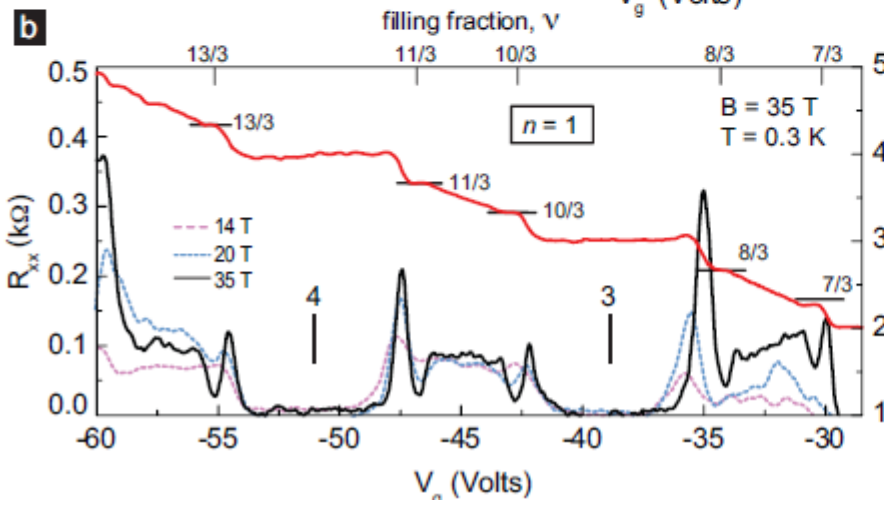
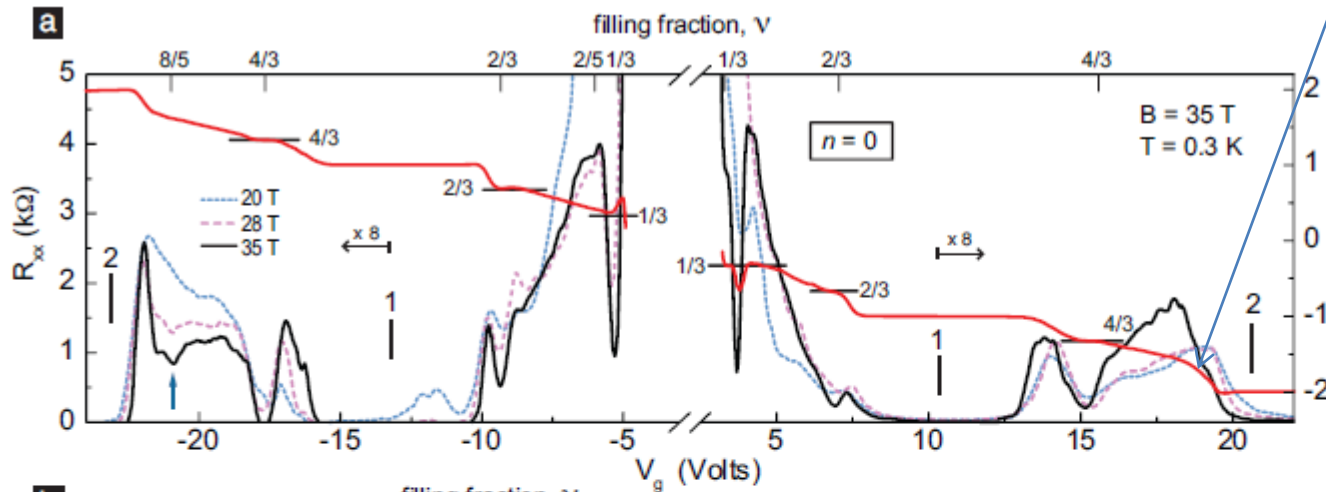
1/3 most developed

Kim group Phys. Rev. Lett. 106, 046801 (2011)

Background on FQHE - hBN

4/3 most developed

5/3 absent



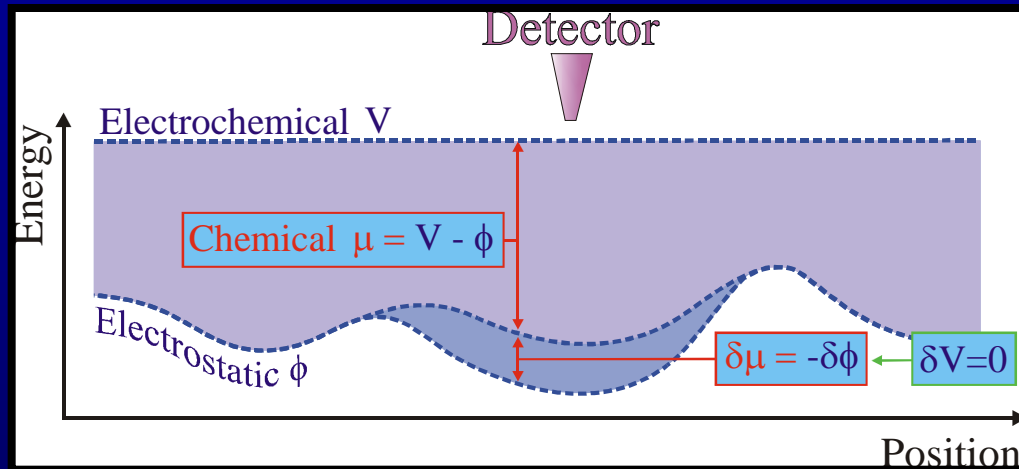
How to Measure Local Density of States ?

$$\left[\frac{\partial n}{\partial \mu} \right]$$

= Density of states

$$\left[\frac{\partial \mu}{\partial n} \right]$$

Inverse (DOS ; Compressibility)



Need to measure

$$\delta\mu$$

Thermodynamic equilibrium



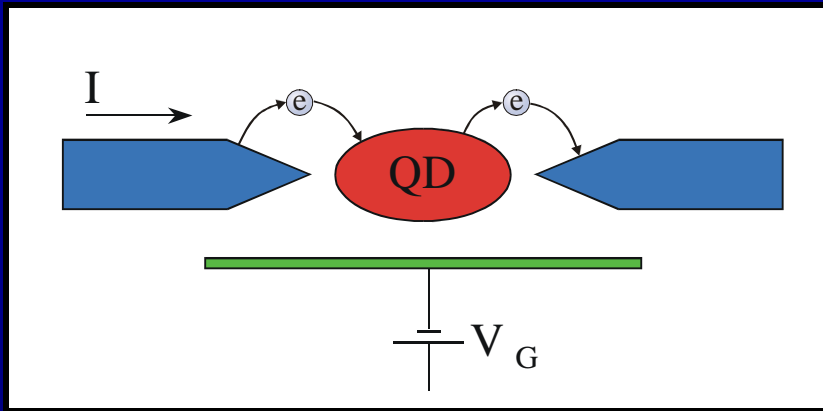
V is constant in space



$$\delta\mu = -\delta\phi$$

If we can measure the local $\delta\phi$
we will immediately get the local $\delta\mu$

Using a SET as a Local Electrostatic Probe

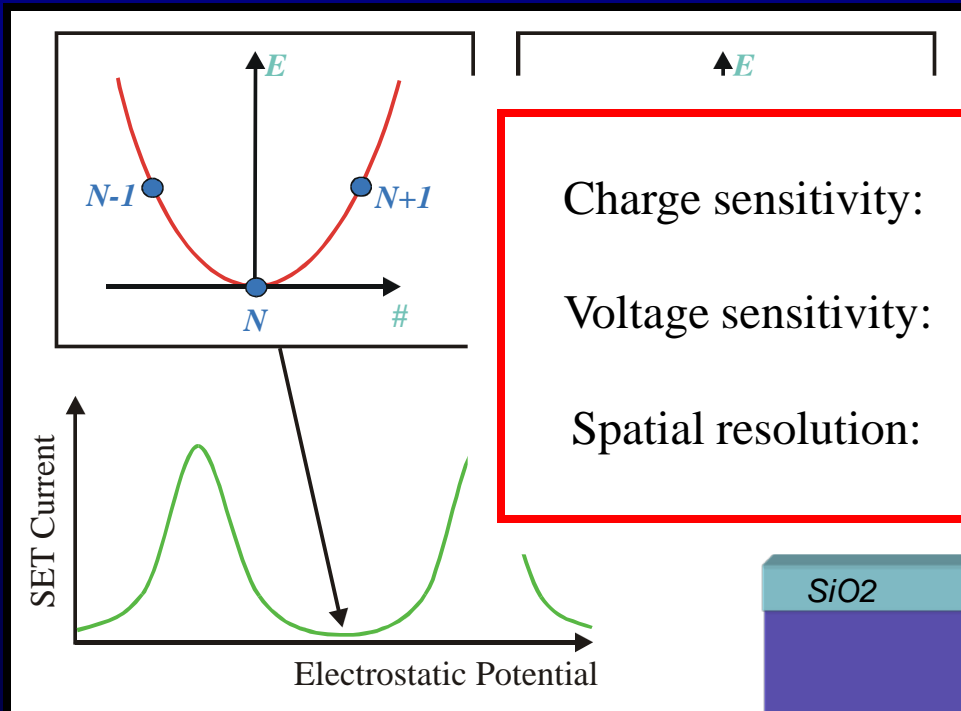


Current flow $N \rightarrow N + 1 \rightarrow N$

Coulomb Blockade $U = \frac{e^2}{c} > kT$

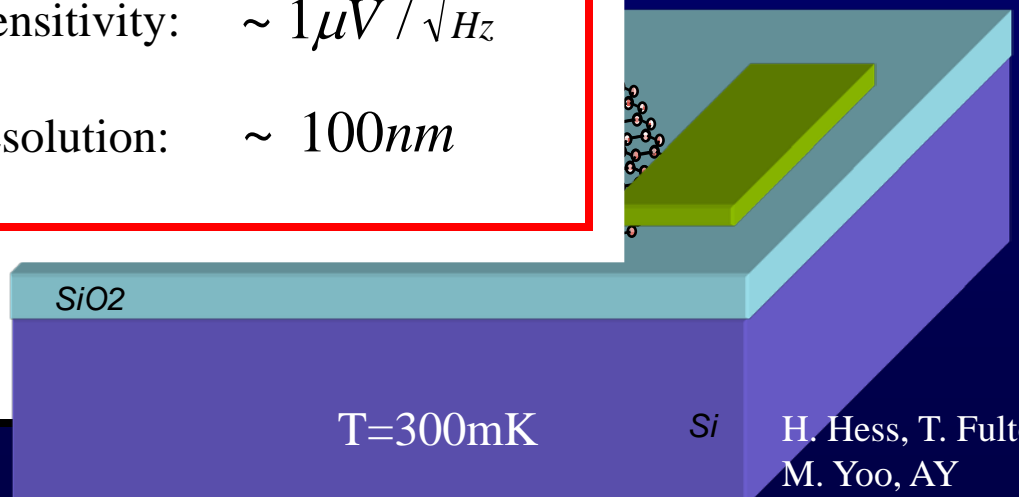
Use graphene as the gate.

By monitoring the current we can extract the local electrostatic potential.



- Charge sensitivity: $\sim 10^{-4} e / \sqrt{\text{Hz}}$
- Voltage sensitivity: $\sim 1 \mu\text{V} / \sqrt{\text{Hz}}$
- Spatial resolution: $\sim 100\text{nm}$

Single Electron Transistor

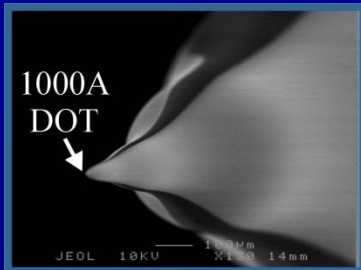


T=300mK

Si

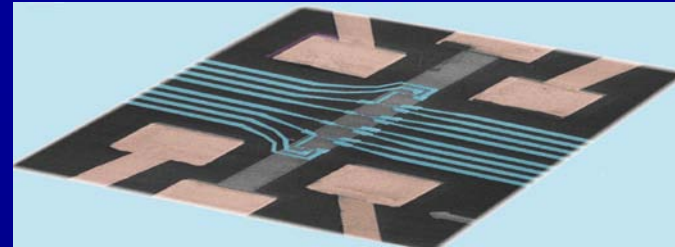
H. Hess, T. Fulton,
M. Yoo, AY

Local Measurement of DOS



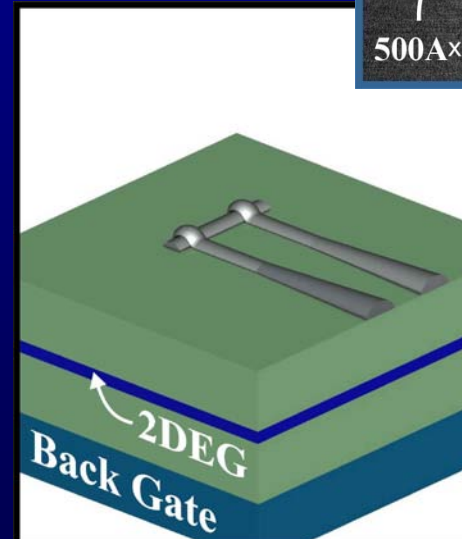
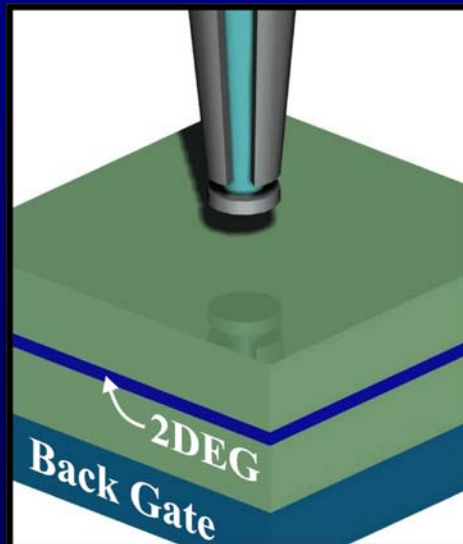
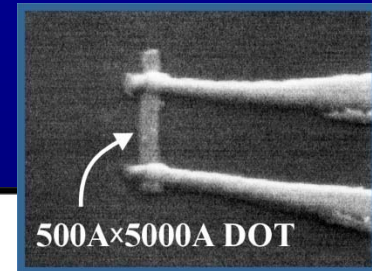
Scanning

T=300mK



Fixed

T=50mK



Metal-Insulator
Transition in 2D

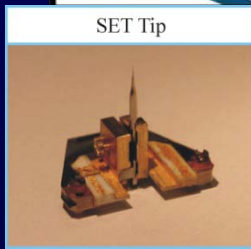
S. Ilani, et. al.,

PRL 84 (2000)

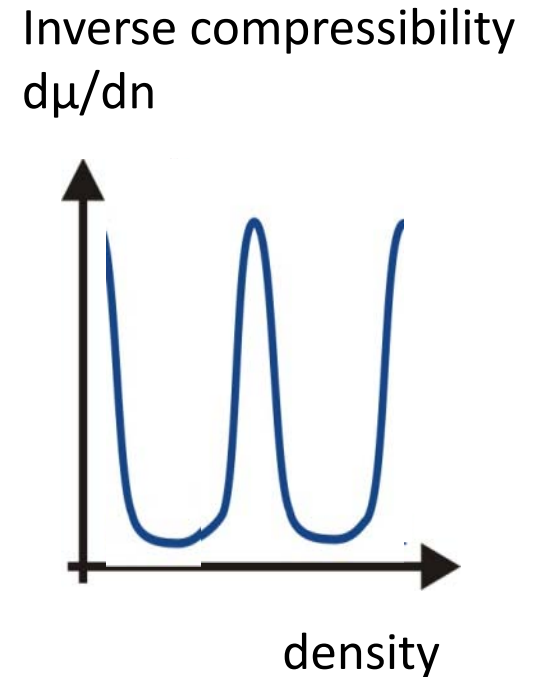
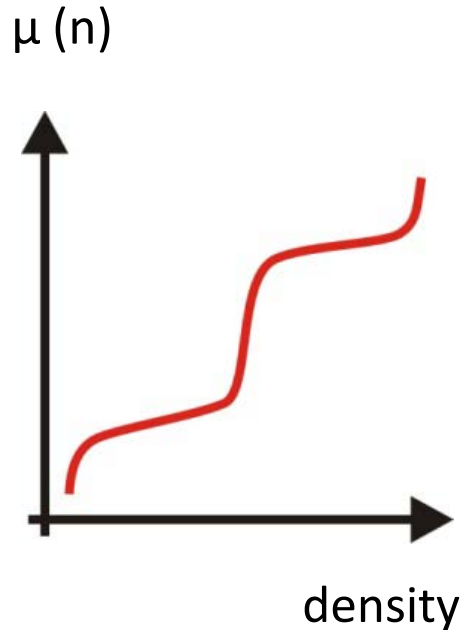
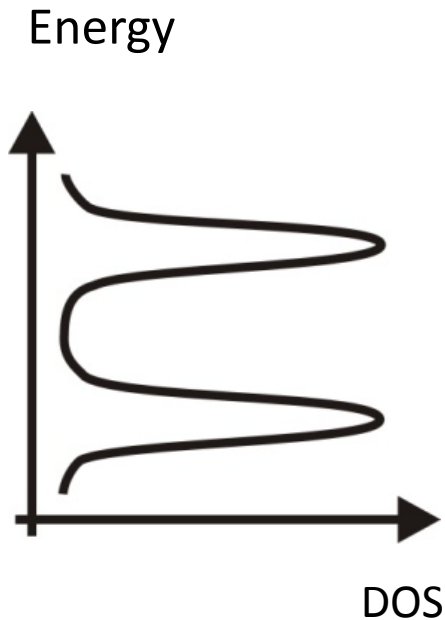
Science 292 (2001)

Simultaneous Transport & Local Potential

S. Ilani et al,
Nature 328 (2004)
Martin et al,
Science (2004)



Inverse compressibility



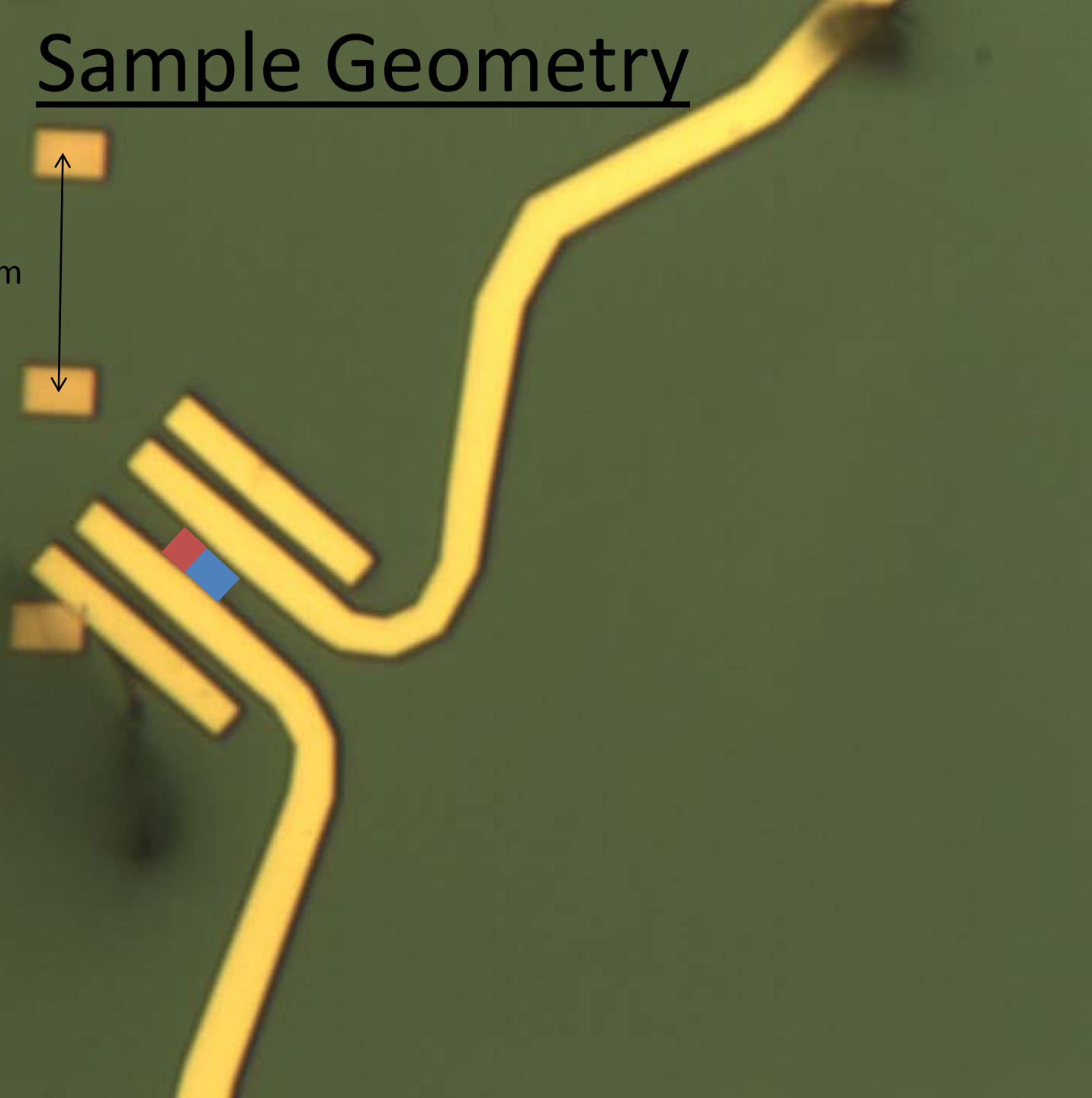

dn : AC voltage on backgate

$d\mu$: Single Electron Transistor

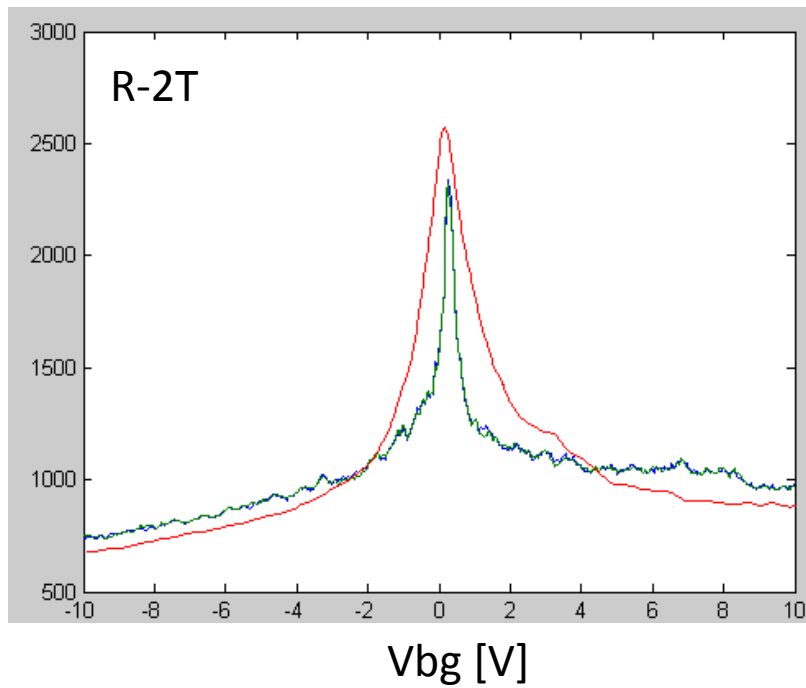
$1\mu\text{V}$, 100nm , $B = [0 - 12 \text{ T}]$, UHV, 300mK

Sample Geometry

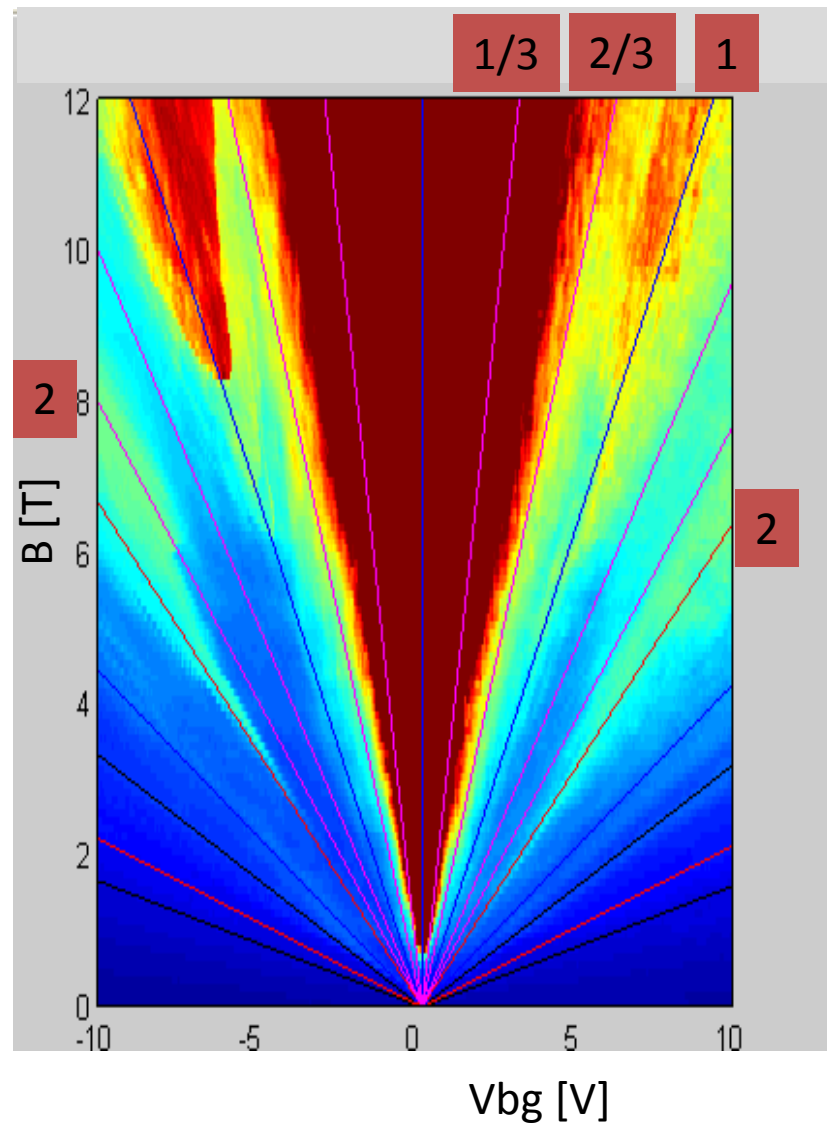
10μm



Transport



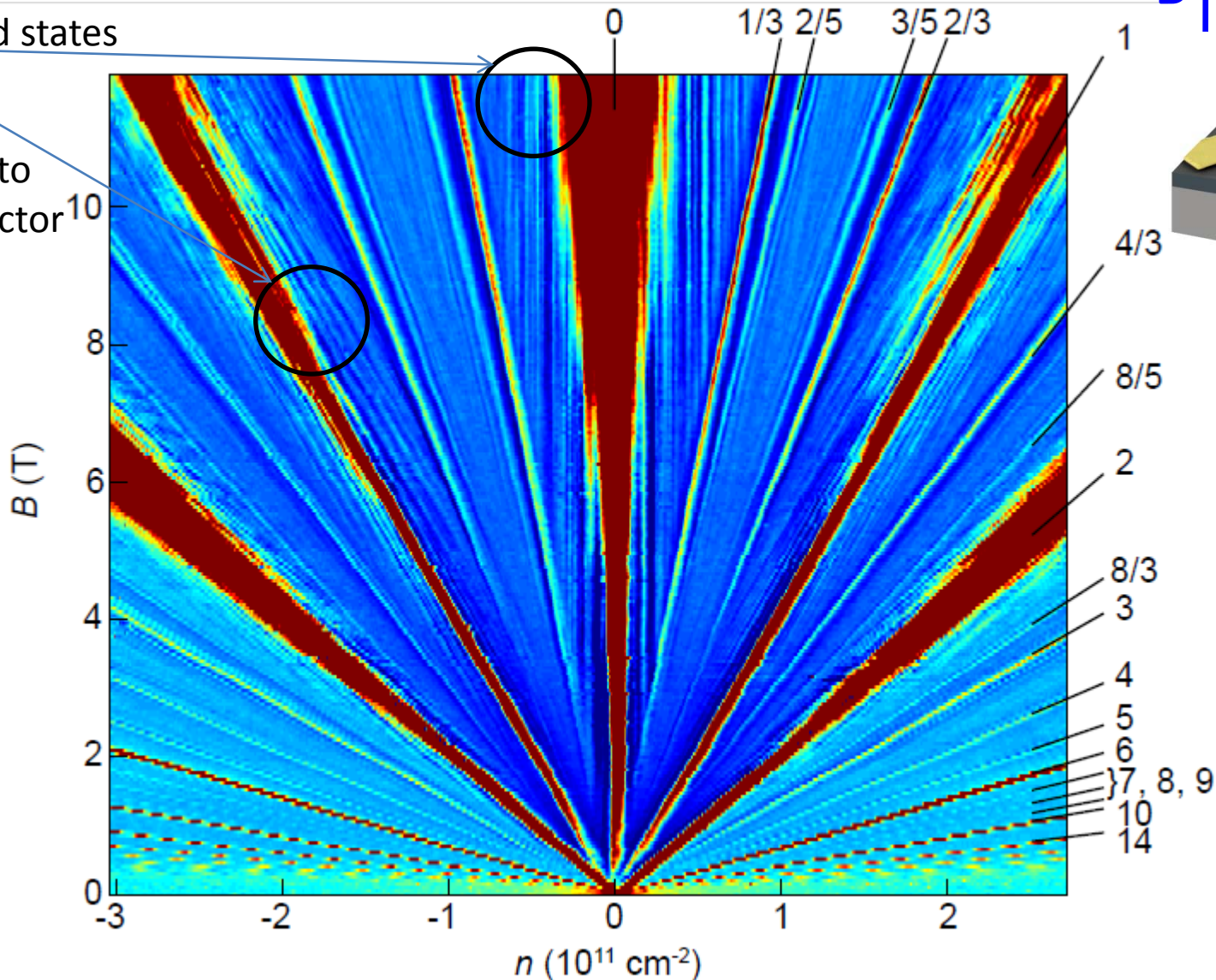
Red: After first round of current annealing
Blue, Green: New



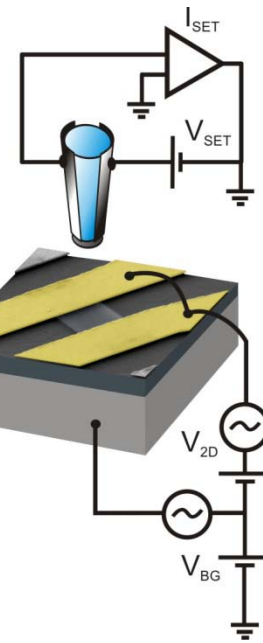
Inverse Compressibility

Localized states

Parallel to filling factor



$B \uparrow$



-2 0 2 4 6 8



$d\mu/dn$ (10^{-10} meV cm^2)

B. E. Feldman, AY, et al, arXiv: 1201.5128

Lowest Landau Level

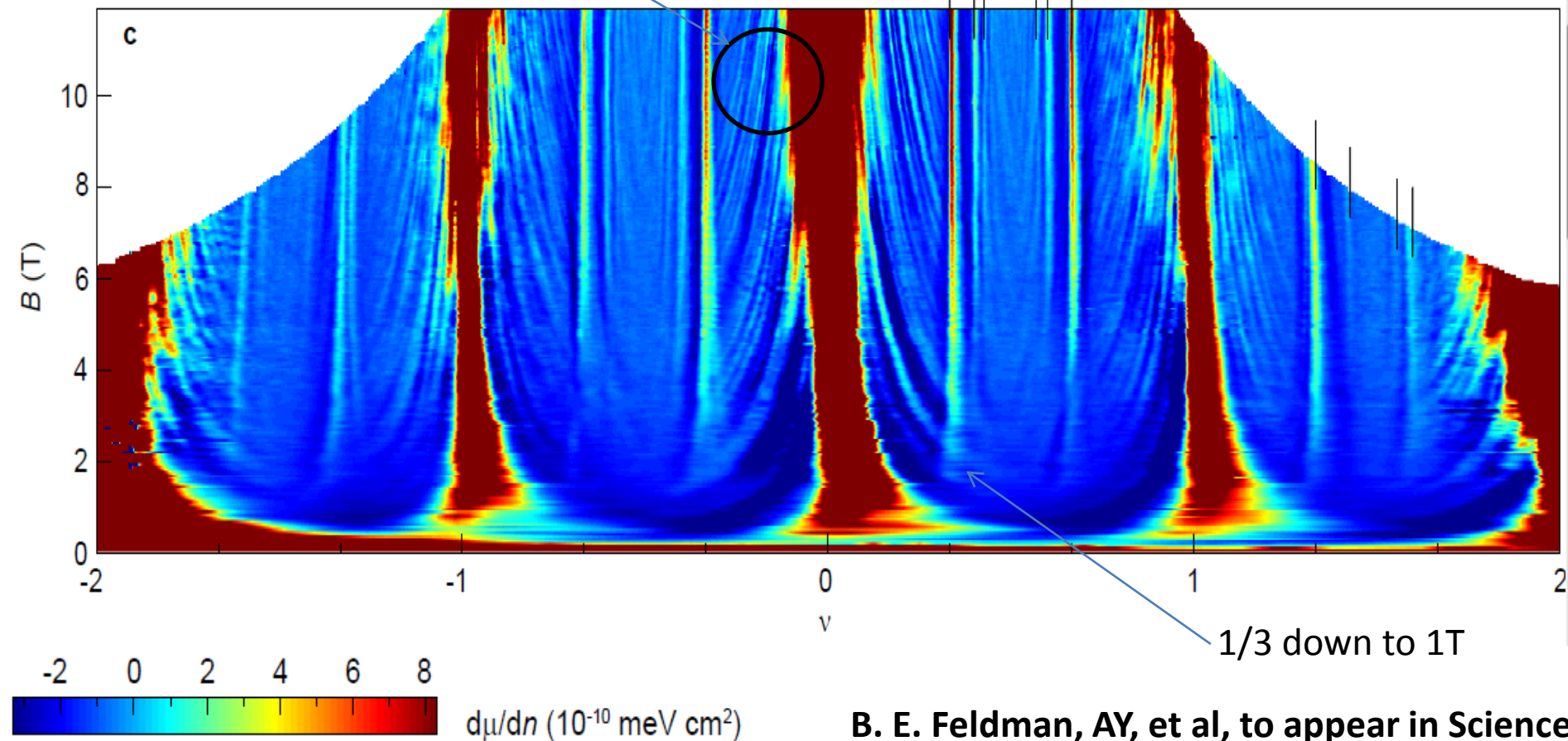
Localized states

N=0 Landau Level

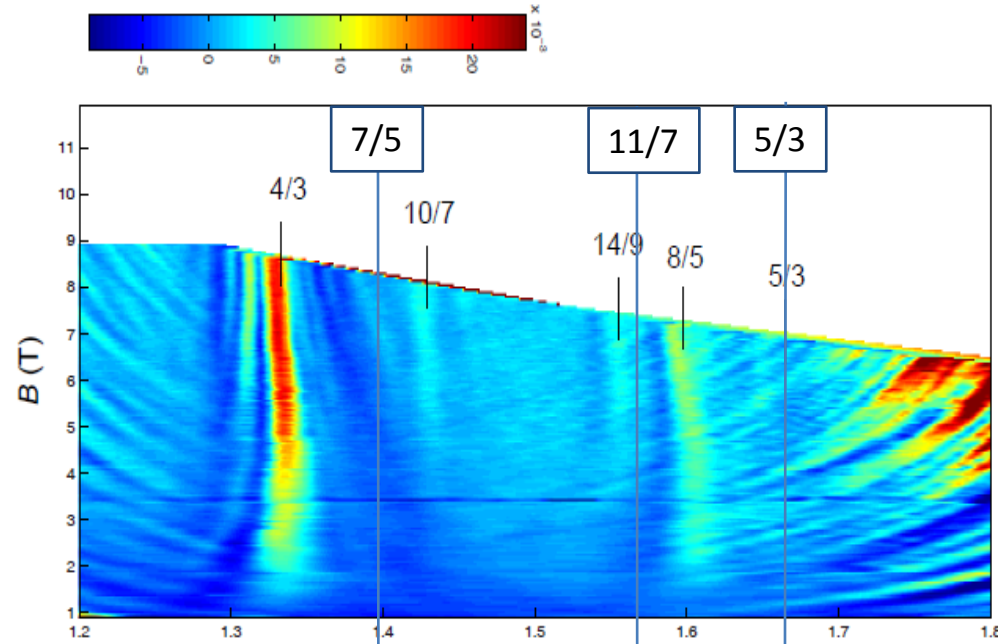
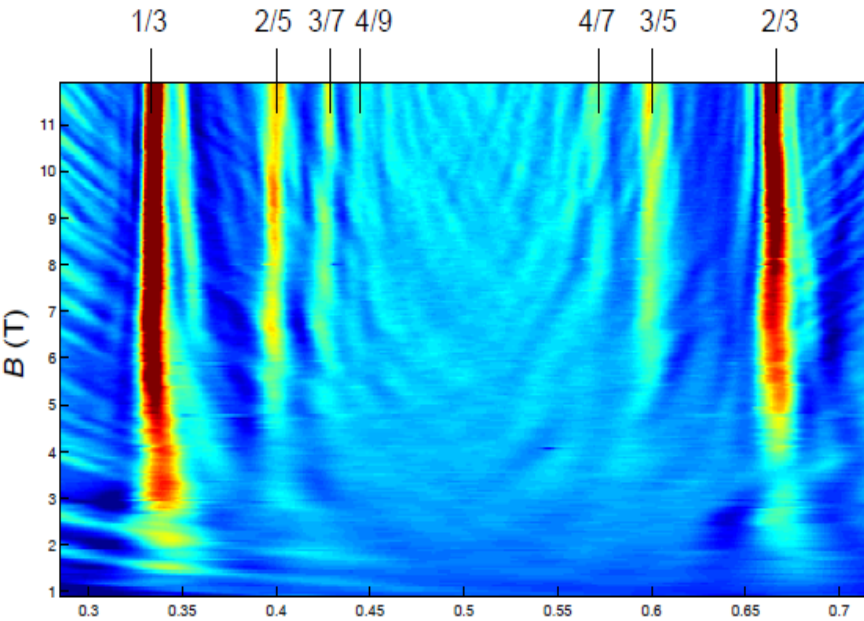
4 fold degeneracy – spin and valley

Valley ordered / CAF

Valley and spin ordering

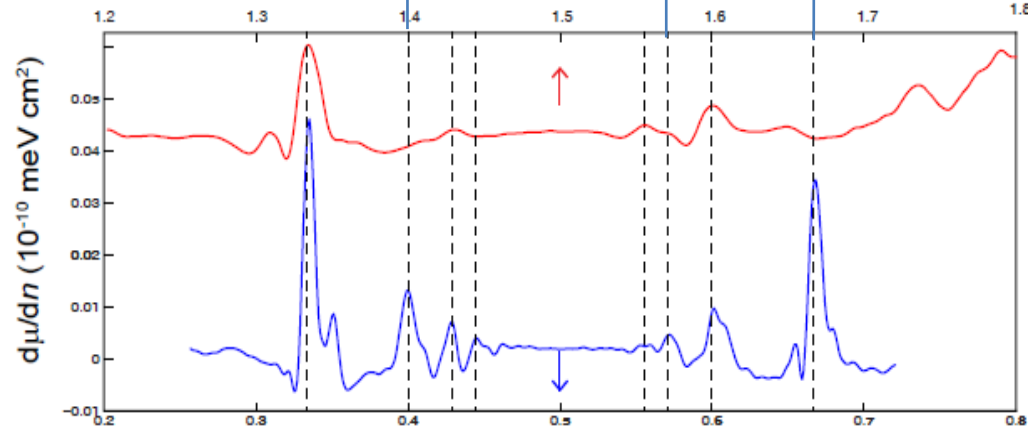
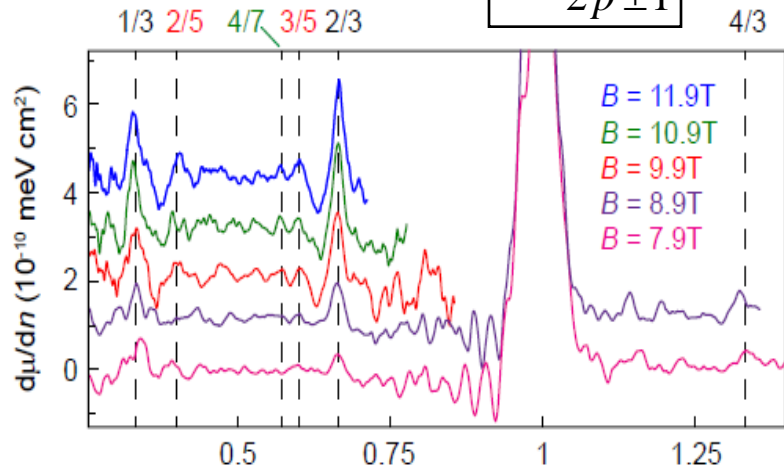


Fractions in the Lowest Landau Level

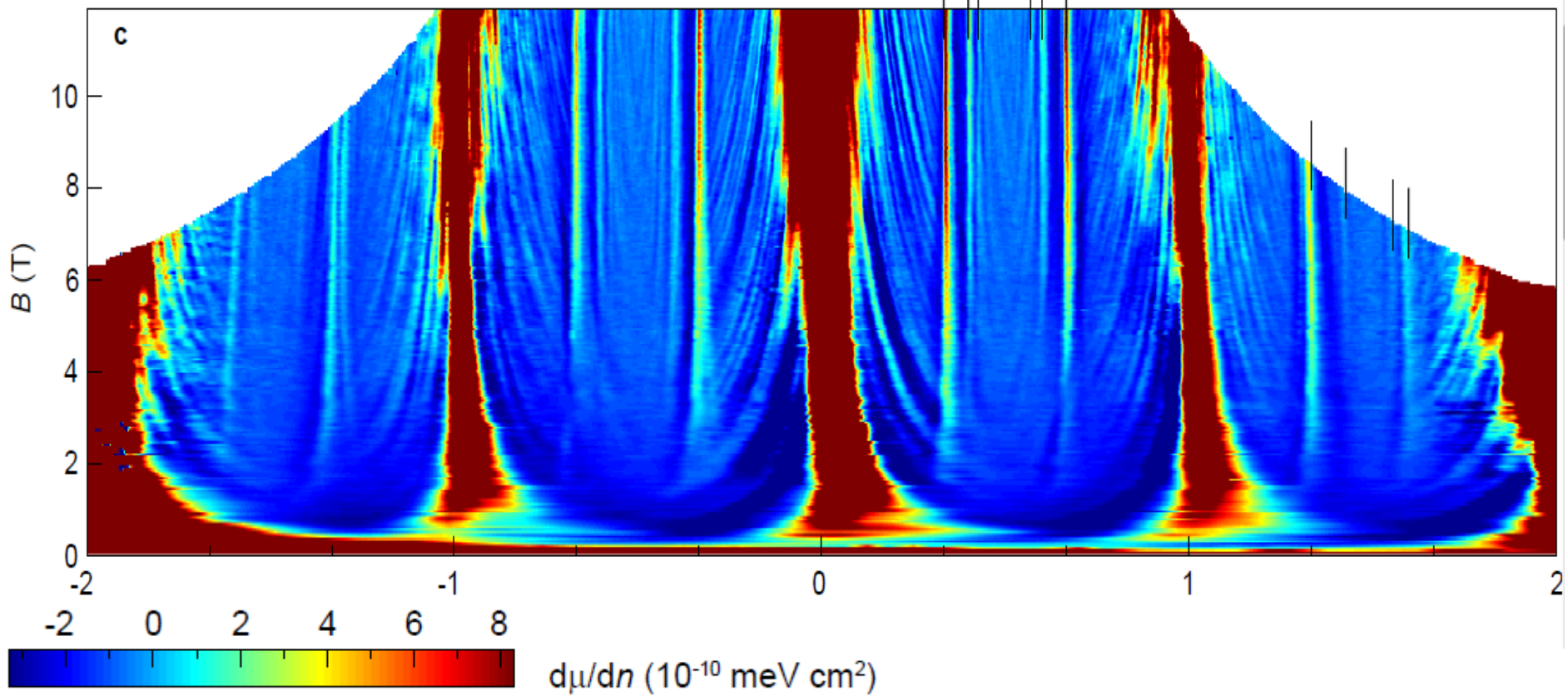
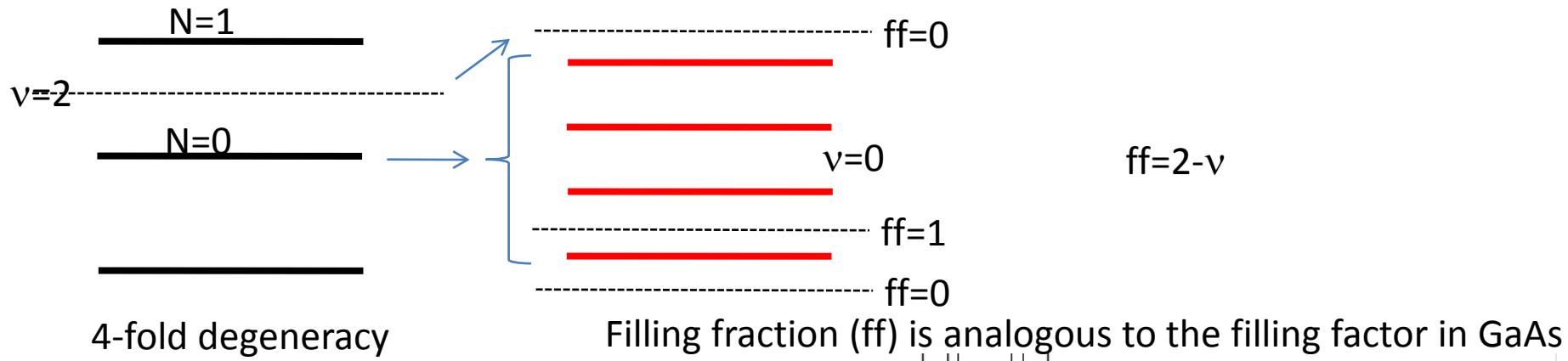


No CF degeneracy's

$$\nu = \frac{p}{2p \pm 1}$$

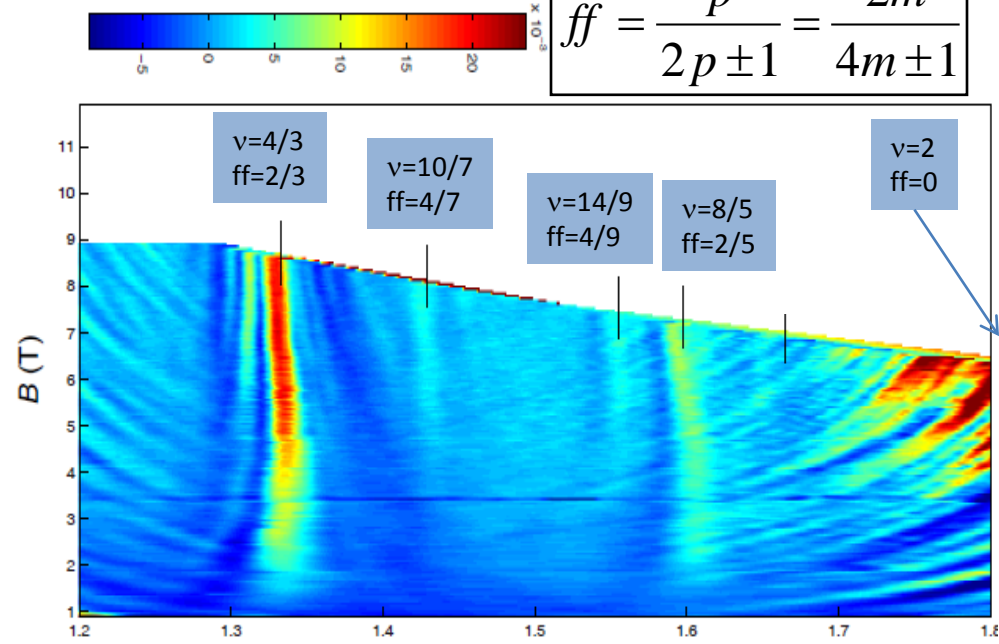
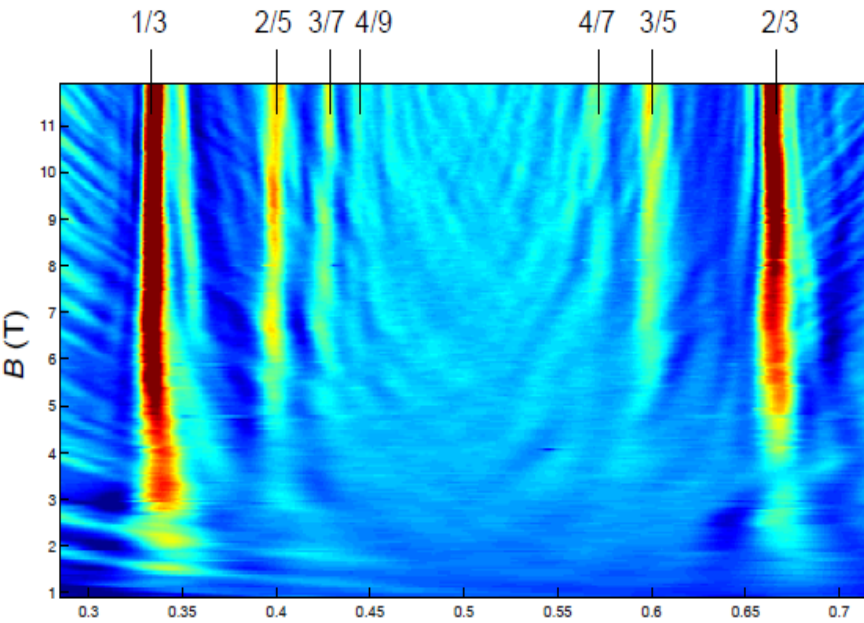


Filling Fraction vs Filling Factor



Missing Filling Fractions

$$ff = \frac{p}{2p \pm 1} = \frac{2m}{4m \pm 1}$$

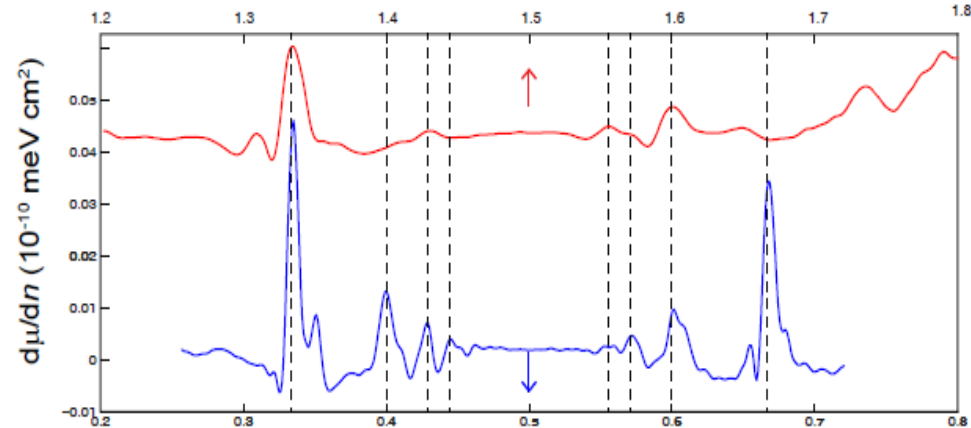
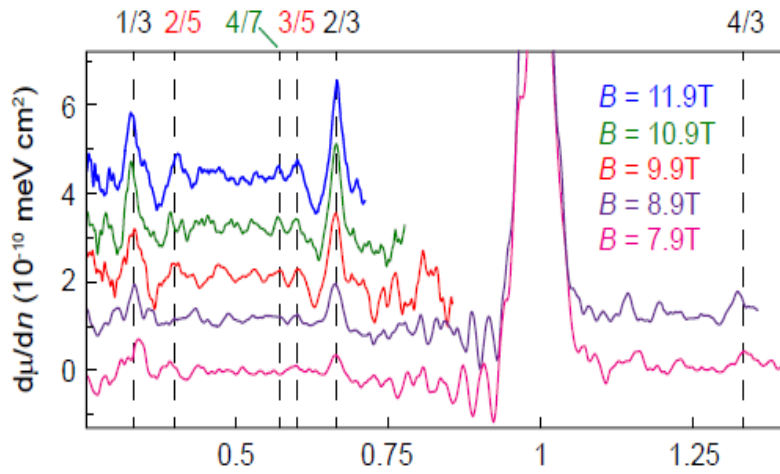


All fractions present ν

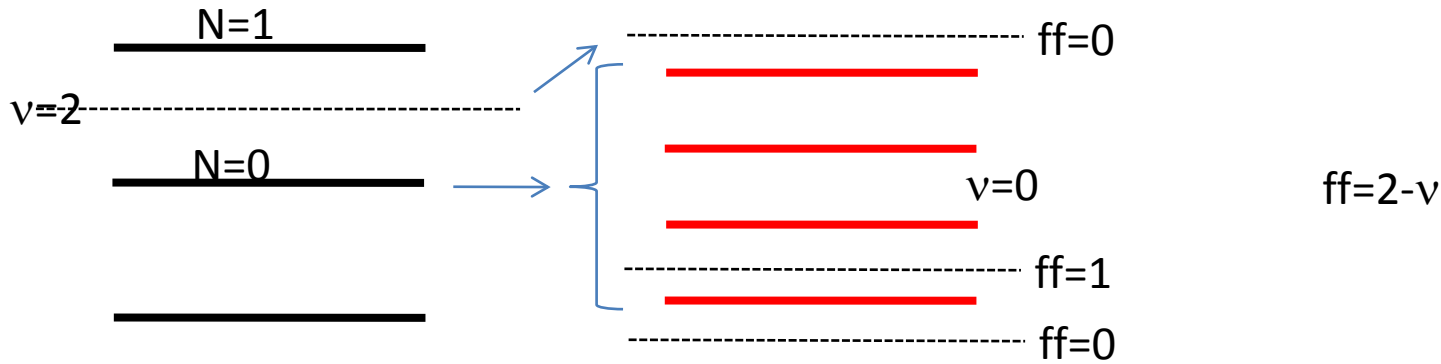
Only even numerators ν - Have CF degeneracy's

$ff=1+(2/3, 3/5, 4/7, 5/9, \dots, 4/9, 3/7, 2/5, 1/3)$

$ff=2/3, 4/7, \dots, 4/9, 2/5$

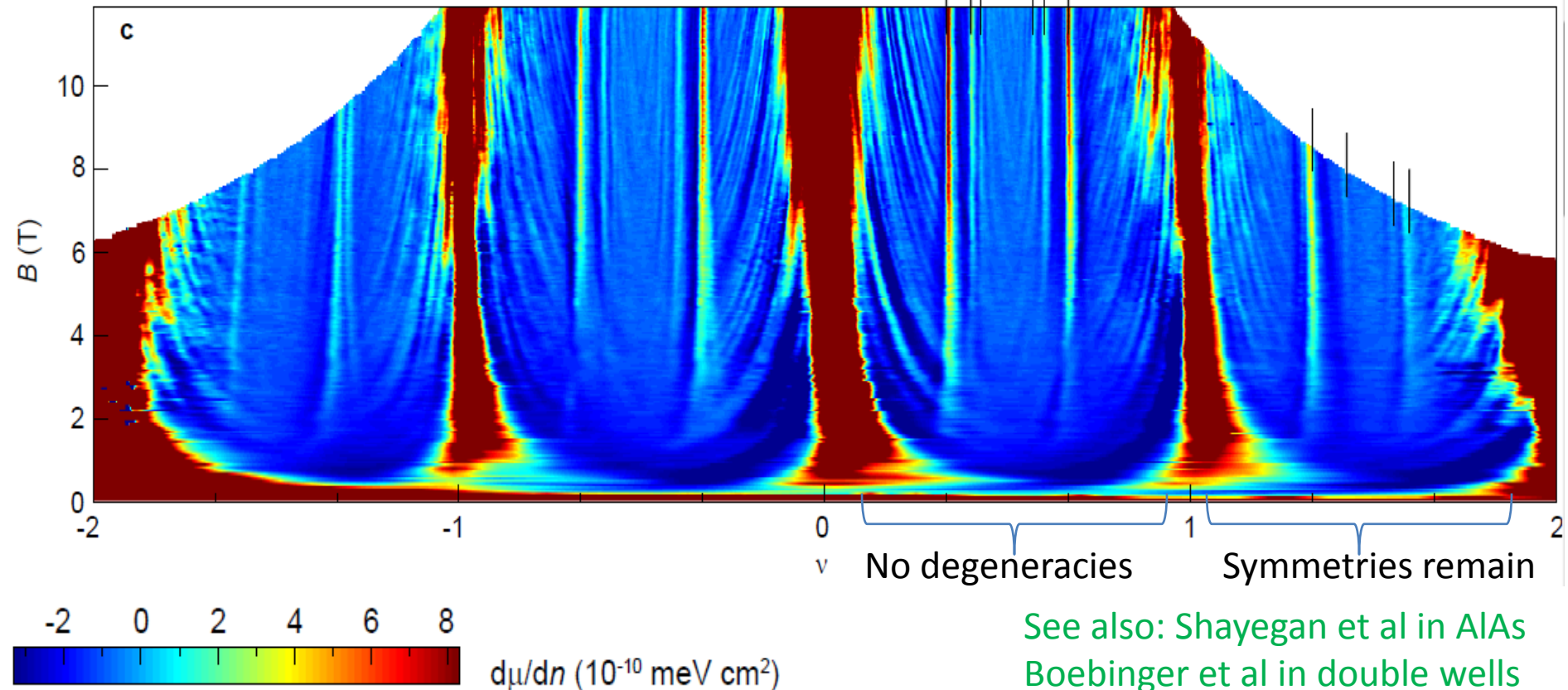


Filling Fraction vs Filling Factor



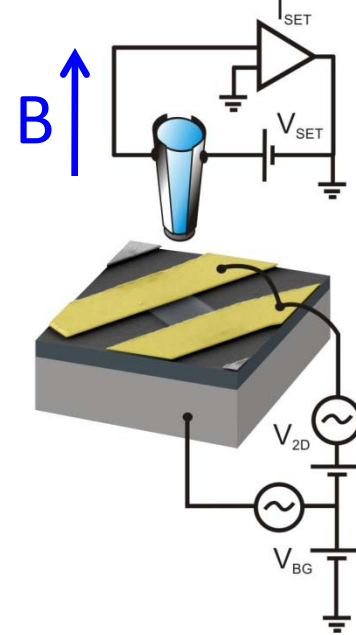
4-fold degeneracy

Filling fraction (ff) is analogous to the filling factor in GaAs



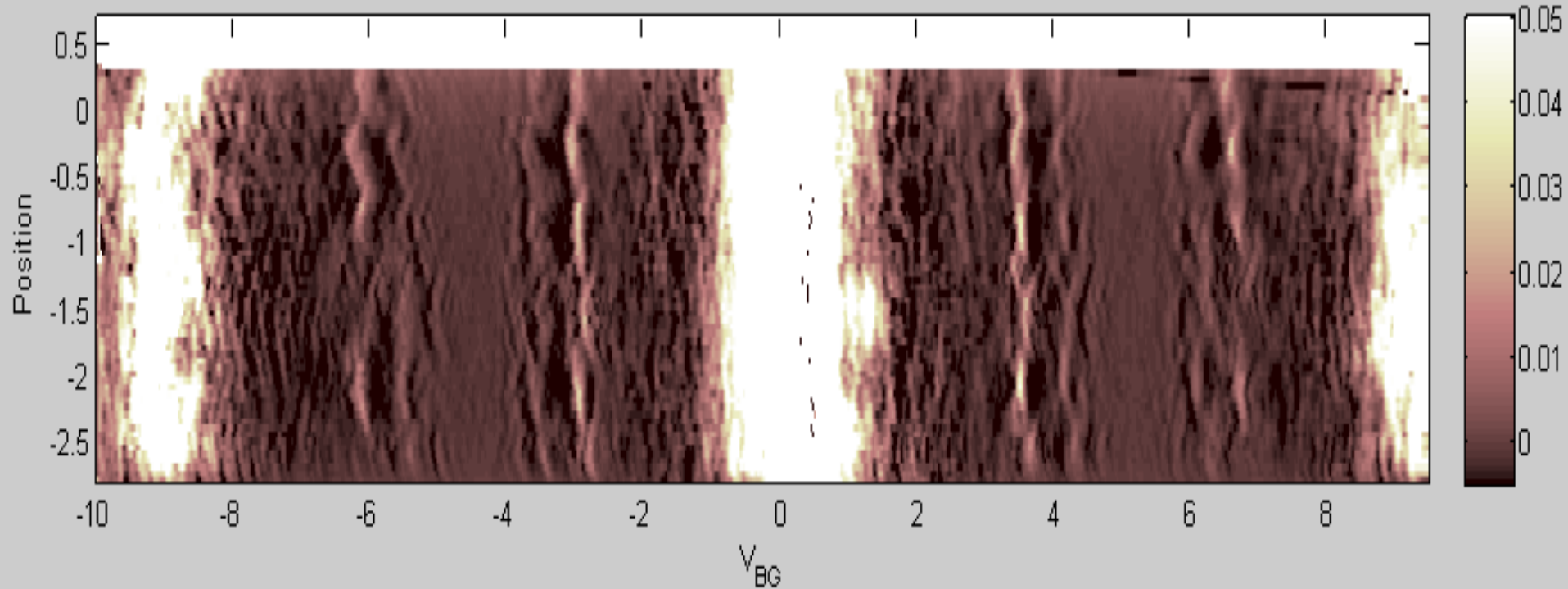
See also: Shayegan et al in AIs
 Boebinger et al in double wells

Spatial Dependence

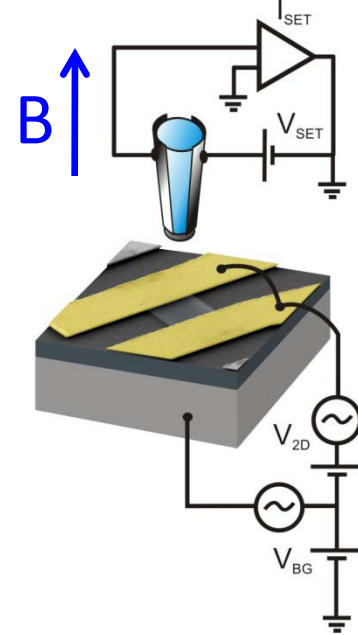


Fractions shift with position

$B = 12 \text{ T}$

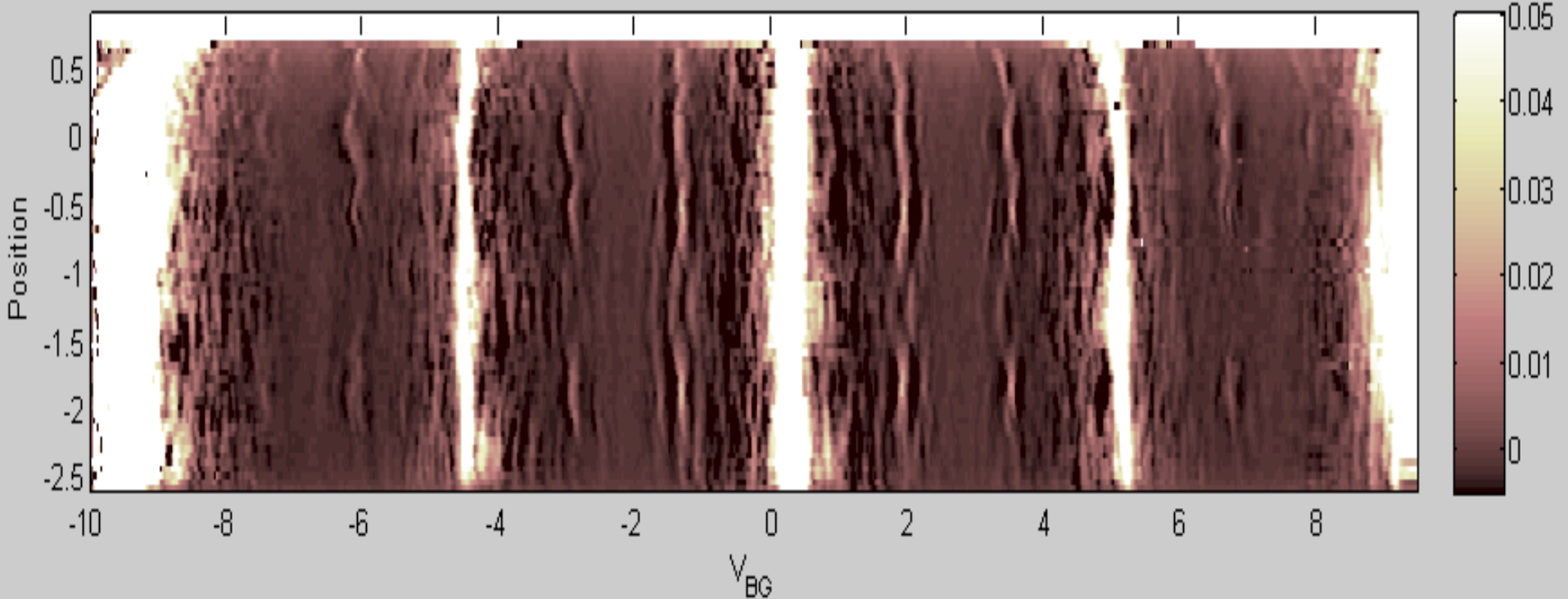


Spatial Dependence



Fractions shift with position

$B = 6 \text{ T}$

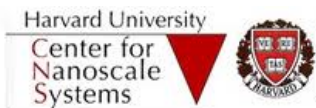
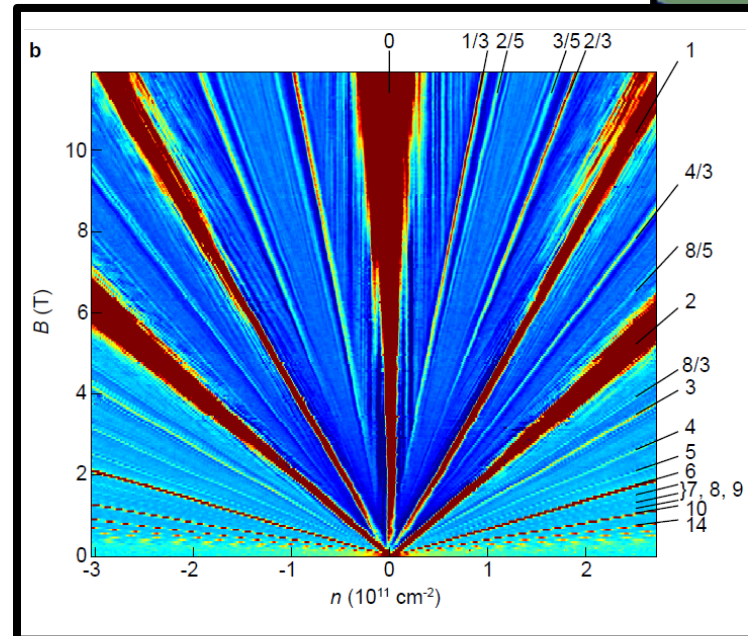
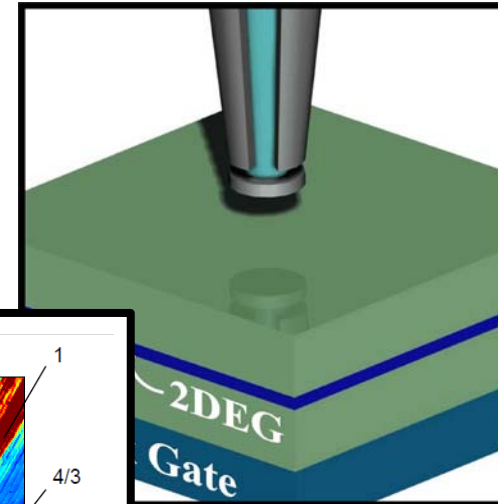


Effects of Interactions in Suspended Graphene

Ben Feldman, Andrei Levin, Amir Yacoby, Harvard University

- Broken and unbroken symmetries in the lowest LL:
 - spin and valley symmetries.
- FQHE

Discussions with Bert Halperin
and Dima Abanin



In collaboration with
Benjamin Krauss, Jurgen Smet, MPI Stuttgart